

LBMO

CMD47

2025/9/3 Lecture 7 (15:00-16:30)

Functional Oxide Spintronics and the material design

SANKEN, Osaka University, Teruo Kanki

E-mail: kanki@sanken.osaka-u.ac.jp)

STO(100)

2 nm

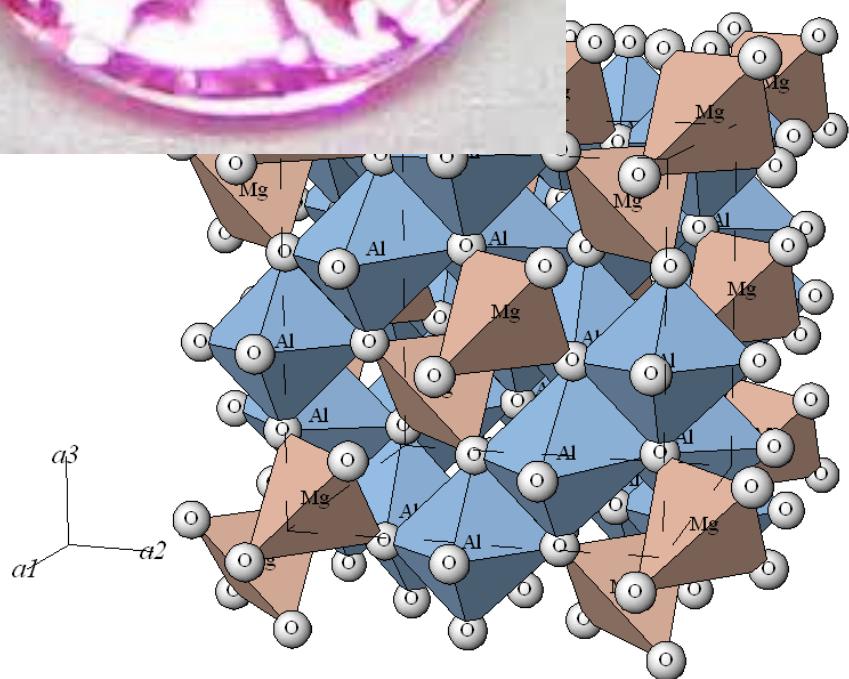


Ceramics



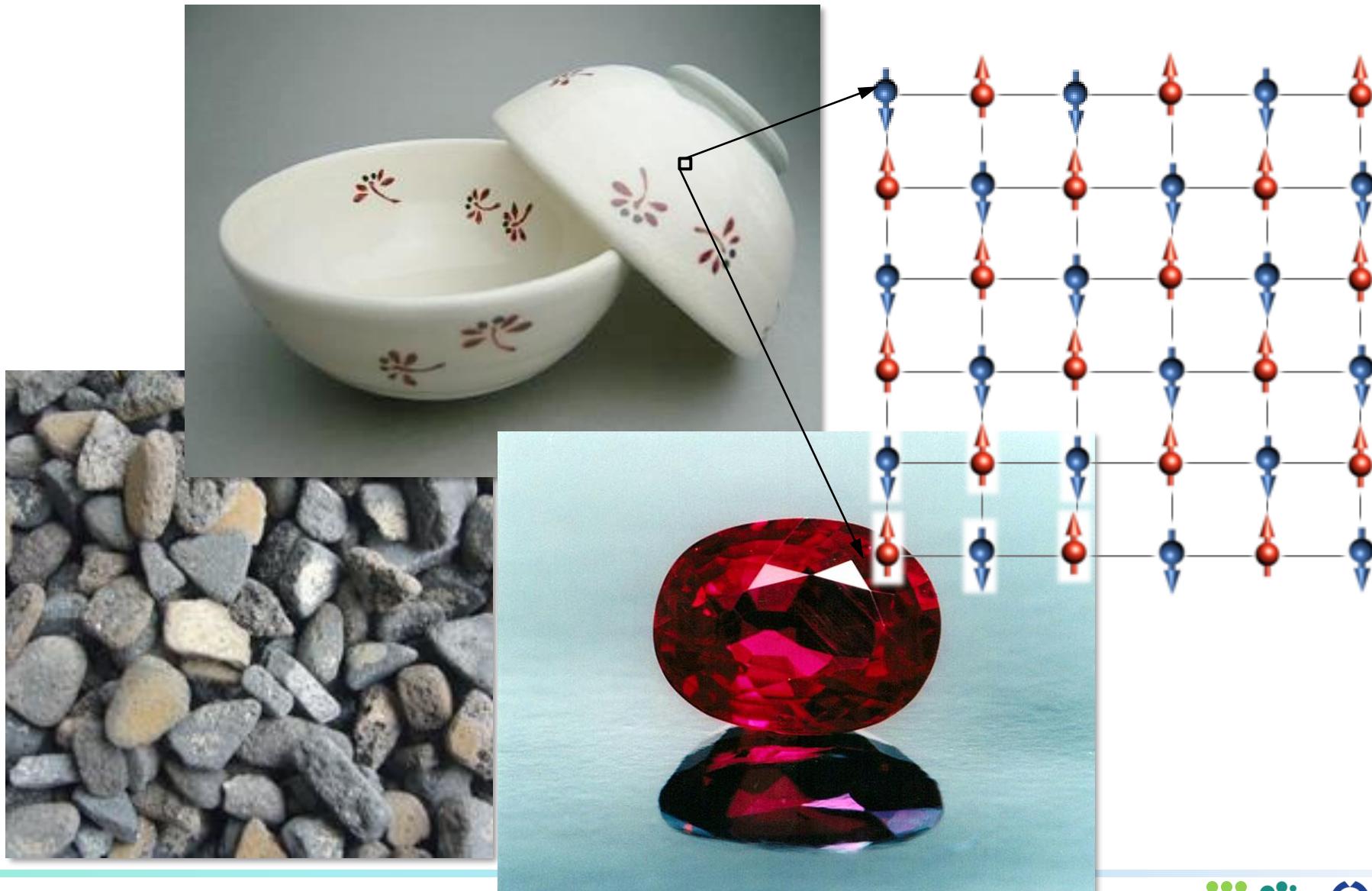


Jewelry (Spinel, Garnet)



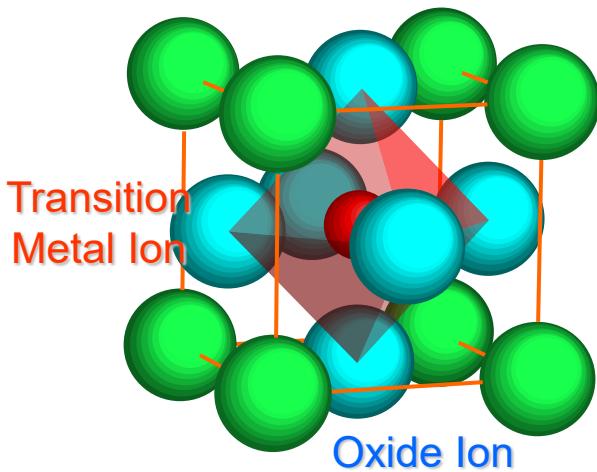


Functional Oxides





Transition Metal Oxides



22 Ti 47.87 チタン Titanium	23 V 50.94 バナジウム Vanadium	24 Cr 52.00 クロム Chromium	25 Mn 54.94 マンガン Manganese	26 Fe 55.85 鉄 Iron	27 Co 58.93 コバルト Cobalt	28 Ni 58.69 ニッケル Nickel	29 Cu 63.55 銅 Copper
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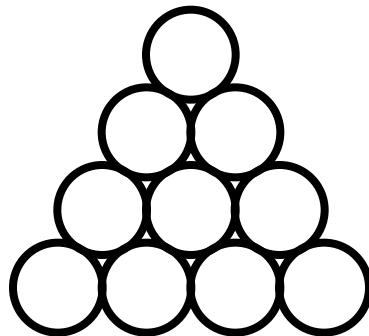
Ferro dielectrics Anti-/Ferro magnetics High temperature superconductors
Piezoelectrics Colossal MR Conductors

Memory Magnetic head Magnetic recorder
(DRAM, FRAM, RRAM) Josephson junction
Memory (MRAM) electrode SQUID
Piezoelectric devices Bolometer

Information processing and data storage materials related with our daily life

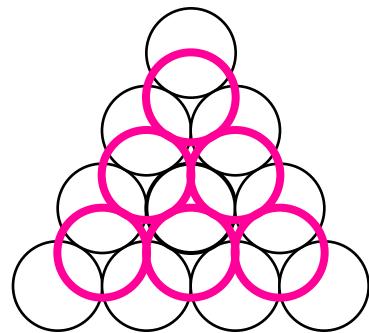


Face-centered cubic => Closed pack structure



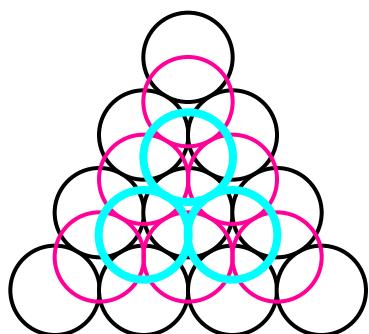
ooooo

1st layer



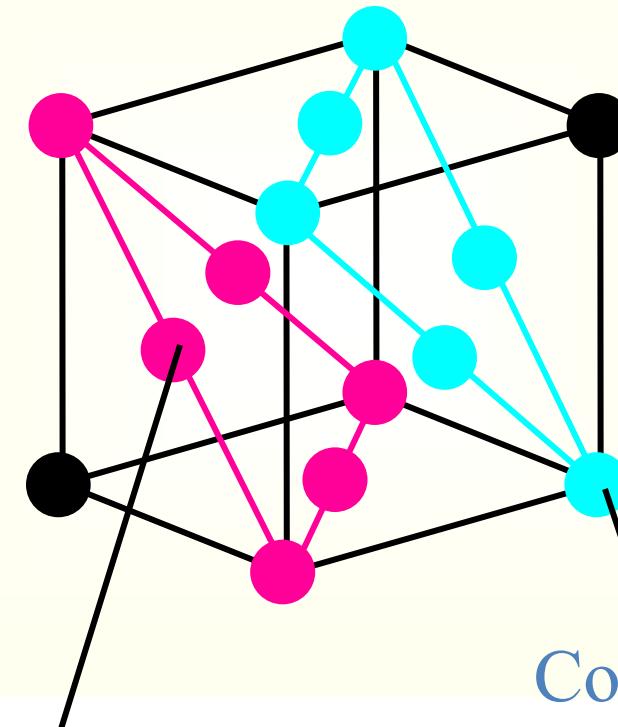
ooooo

2nd layer



ooooo

3rd layer



Center face

$1/2 \times 6$ parts



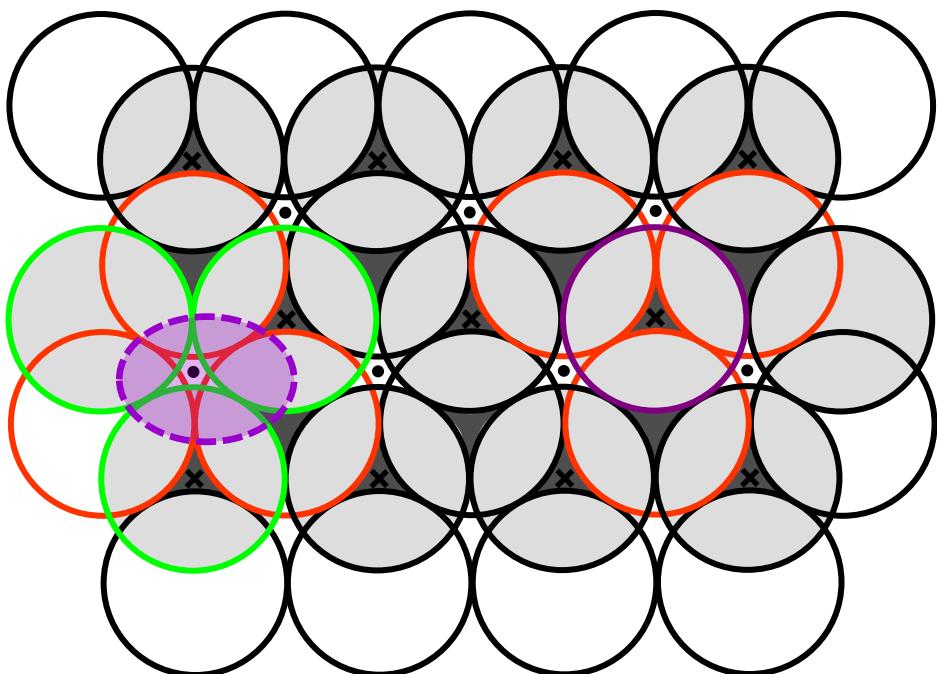
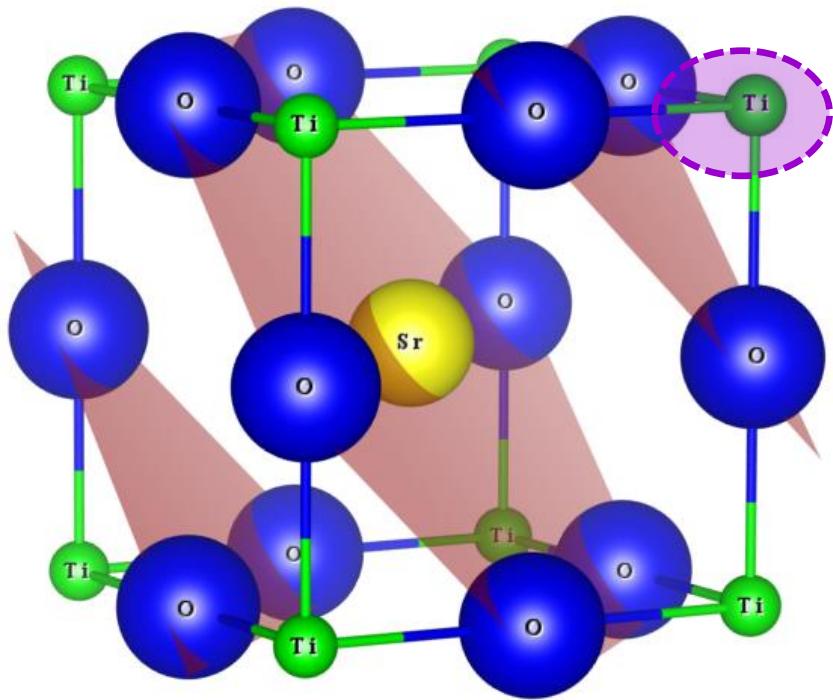
Perovskite structure: ABO_3 e.g. SrTiO_3

Interspace of close packed oxide ions : **Octahedral interspace**

$$\text{O}^{2-} = 1.40 \text{ \AA},$$

$$\text{Sr}^{2+} = 1.44 \text{ \AA} \text{ (12 coordination)},$$

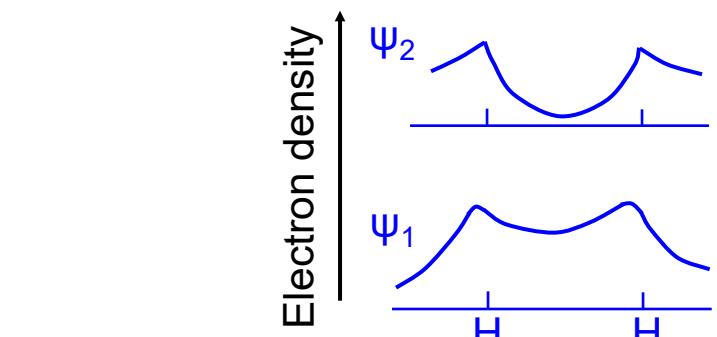
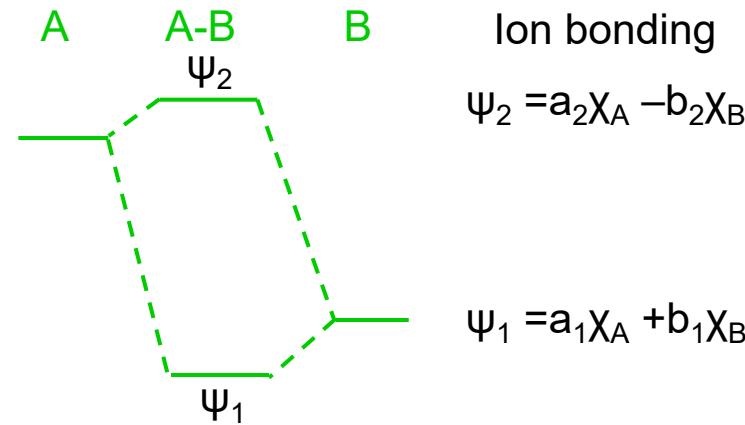
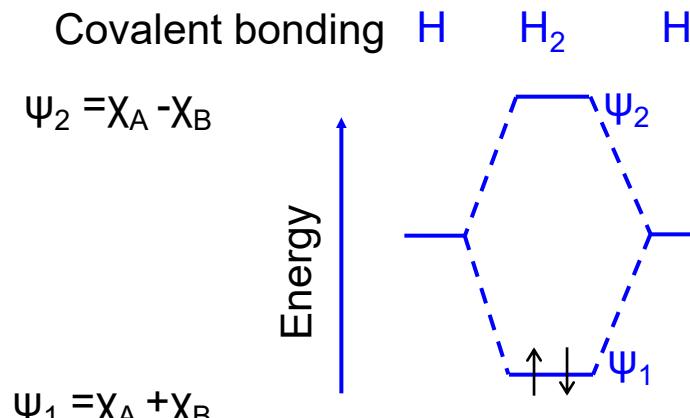
$$\geq 0.414r \quad \text{Ti}^{4+} = 0.42 \text{ \AA} \text{ (6 coordination)}$$



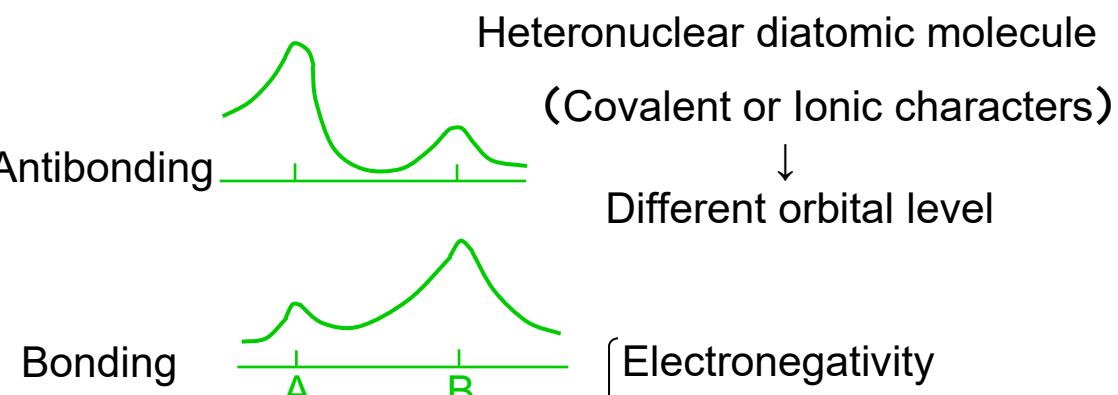


Orbital bonding

Bonding and Antibonding states \rightarrow Valence and Conduction band



(a)

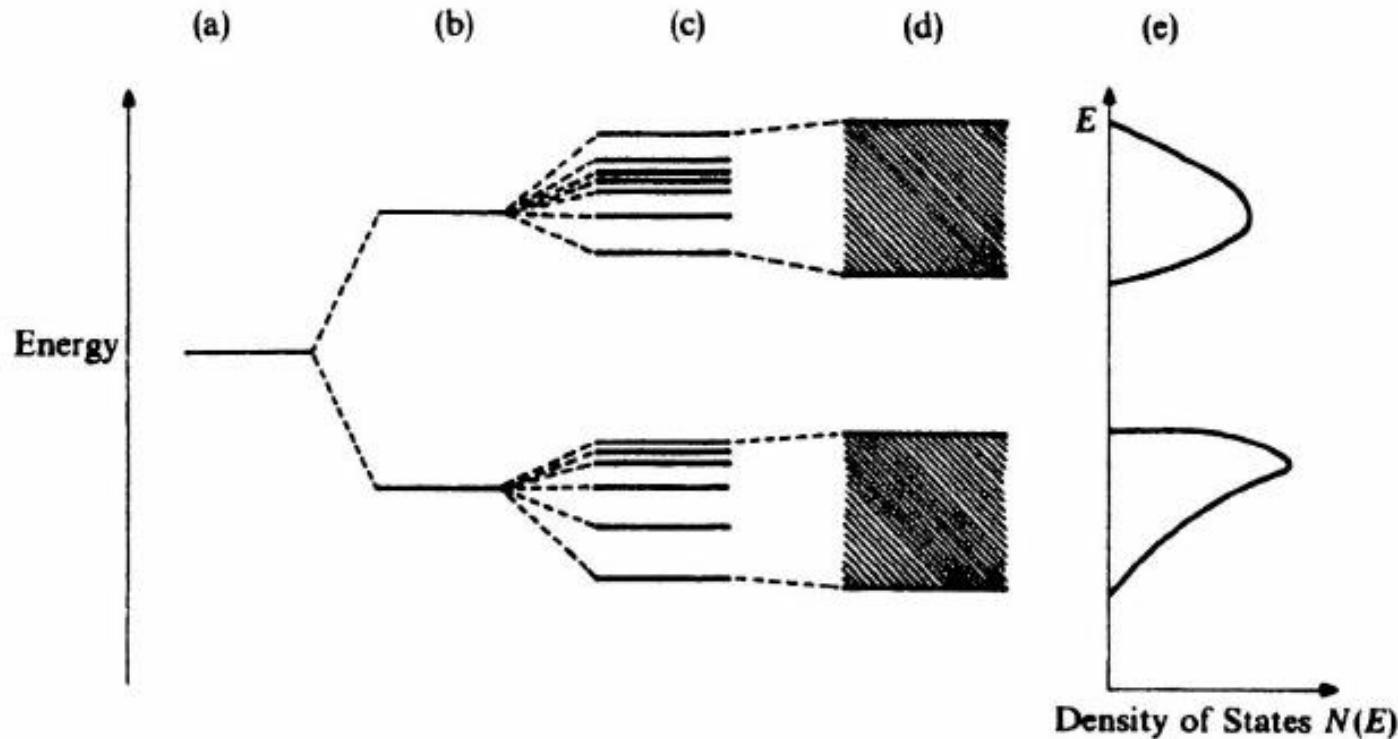


(b)

Electron distributions and energies of molecular orbitals in (a) H_2 and a heteronuclear molecule AB



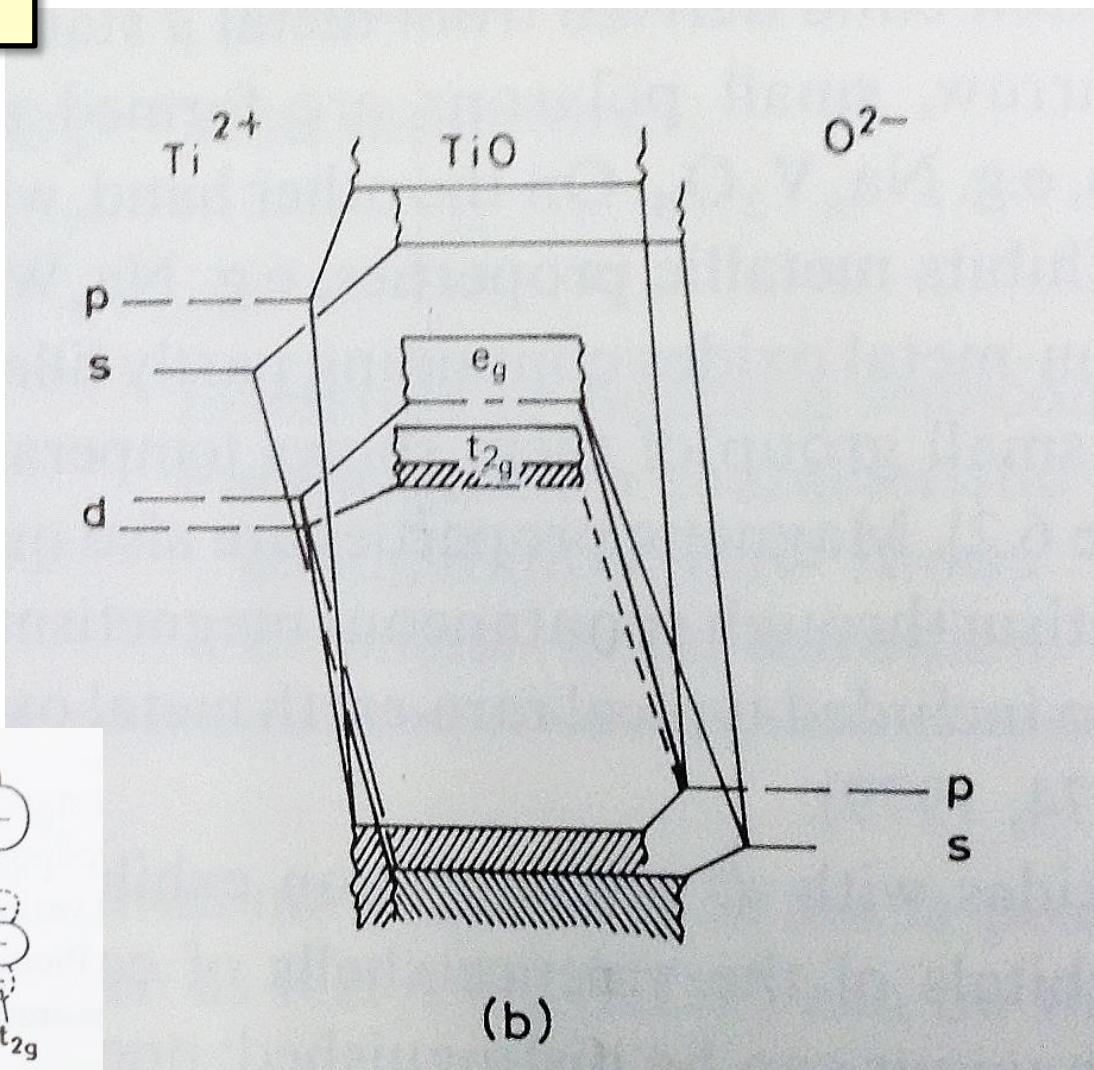
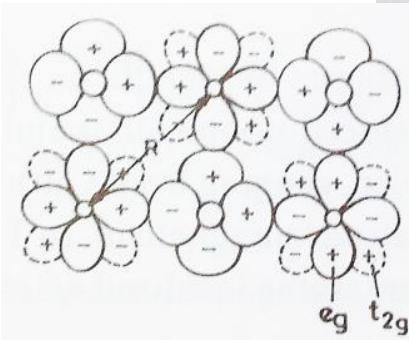
From orbital to band formation



Orbital energies of (a) atom, (b) small molecule, (c) large molecule, (d) solid, and (e) density of states corresponding to (d)



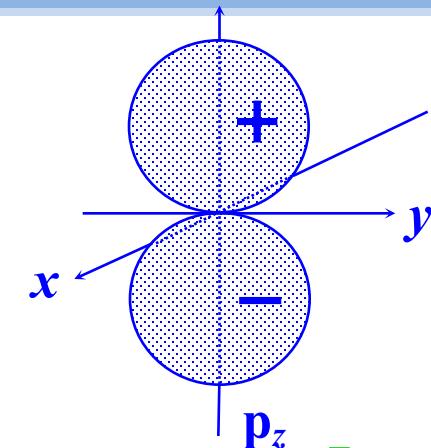
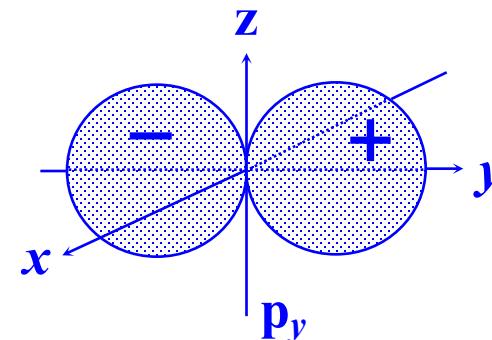
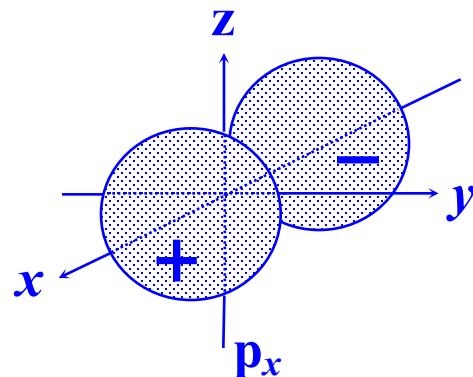
TiO



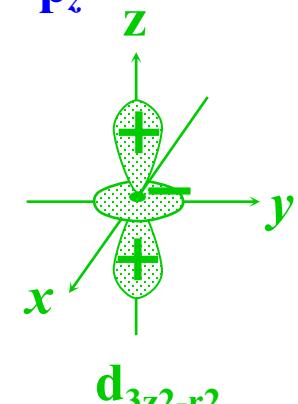
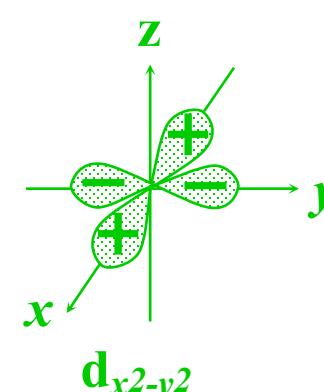
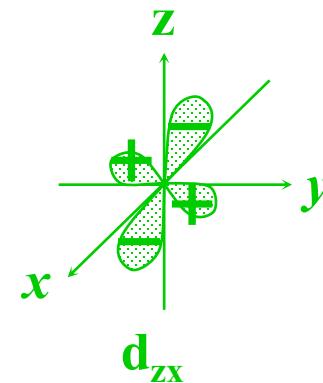
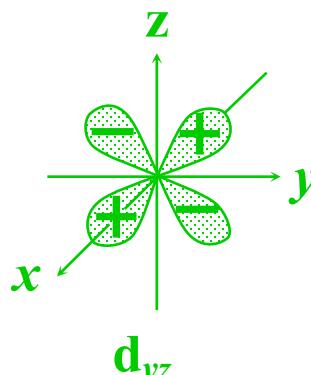
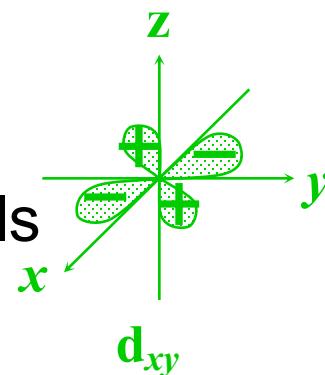


Existence of electrons • Orbital shape

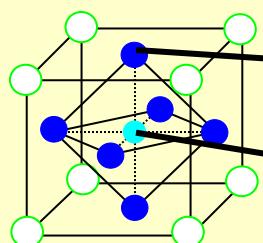
p orbitals



d orbitals



Perovskite structure



Oxygen atom

3d transition metal

Ligand field splitting
(Crystal field splitting)

$$e_g = \begin{array}{c} x^2-y^2 \\ 3z^2-r^2 \end{array}$$
$$t_{2g} = \begin{array}{c} xy \\ yz \\ zx \end{array}$$

Periodic Table of the Elements

2

18

1A	1H Hydrogen	2A	He Helium
1s 1 -1 2s 2p 2s 2p 2p 3s 3p 2p 3s 3p 3s 3p 3s 3p 3p 3d 4s 3p 3d 4s 3d 4p 3d 4p 4s 3d 4p 4s 3d 4p 4p 4d 5s 4p 4d 5s 5s 4f 5p 5s 4f 5p 5p 5d 6s 5p 5d 6s 6s 4f 5d 7s 6s 4f 5d 7s 7s 5g 6f 8s 7s 5g 6f 8s	oxidation states in compounds: important, most important (for easier reading, arabic numerals are used instead of the correct roman ones)	electron configuration $[Ar] 3d^6 4s^2$ 6s 2, 6s -2 [Ar] 3d^6 4s^2 6s 2, 6s -2	atomic radius in pm (half the interatomic distance for the element; α-Fe in this example) covalent radius for single bonds in pm (after Pauling; radii for polar and multiple bonds are shorter) ionic radius in pm with oxidation number coordination number (Cr, Mn, Fe, Co: values for high-spin complexes) van der Waals radius in pm
2	2H Deuterium	2Be Beryllium	He Helium
3	3Li Lithium	3Be Beryllium	He Helium
4	4Na Sodium	4Mg Magnesium	He Helium
5	5K Potassium	5Ca Calcium	He Helium
6	6Rb Rubidium	6Sr Strontium	He Helium
7	7Cs Cesium	7Ba Barium	He Helium
8	8Ra Radon	8Fr Francium	He Helium
9	9Fr Francium	9Rb Rubidium	He Helium
10	10Cs Cesium	10Ba Barium	He Helium
11	11Fr Francium	11Rb Rubidium	He Helium
12	12Cs Cesium	12Ba Barium	He Helium
13	13B Boron	13C Carbon	18Oxygen
14	14N Nitrogen	14C Carbon	16Sulfur
15	15O Oxygen	15N Nitrogen	17Chlorine
16	16Sulfur	16Cl Chlorine	18Argon
17	17Ne Neon	17Ar Argon	He Helium
18	He Helium	He Helium	He Helium

oxidation states in compounds:
important, most important
(for easier reading, arabic numerals
are used instead of the
correct roman ones)

atomic number
name (IUPAC)

element essential to all biological species investigated

essential to at least one biological species

biological function suggested

essential to humans

suggested to be essential to humans

electron configuration
 $[Ar] 3d^6 4s^2$
6s 2, 6s -2
[Ar] 3d^6 4s^2
6s 2, 6s -2

atomic radius in pm (half the interatomic distance for the element; α-Fe in this example)
covalent radius for single bonds in pm (after Pauling; radii for polar and multiple bonds are shorter)
ionic radius in pm with oxidation number
coordination number (Cr, Mn, Fe, Co: values for high-spin complexes)
van der Waals radius in pm

reduction potential E° in V with number (n) of electrons for:
 $E^\circ + ne^- \rightleftharpoons E(s)$ (metals)
 $E^\circ + ne^- \rightleftharpoons E^-$
 $EO_2 + nh^+ + nm^- \rightleftharpoons E(s) + nm/2 H_2 O$
 $1/2 O_2(g) + 2H^+ + 2e^- \rightleftharpoons H_2 O(l)$

electronegativity (Allred and Rochow)

abundance (mass fraction in % of the element in the earth's lithosphere (upper 16 km) plus hydrosphere (oceans) plus atmosphere; mass fraction calculated from natural radioactive series or other natural nuclear reactions)

distribution:

VCH Verlagsgesellschaft, P.O. Box 1260/1280, D-6940 Weinheim (Federal Republic of Germany)
USA and Canada: VCH Publishers, 303 N.W. 12th Avenue, Deerfield Beach, FL 33442-1705 (USA)
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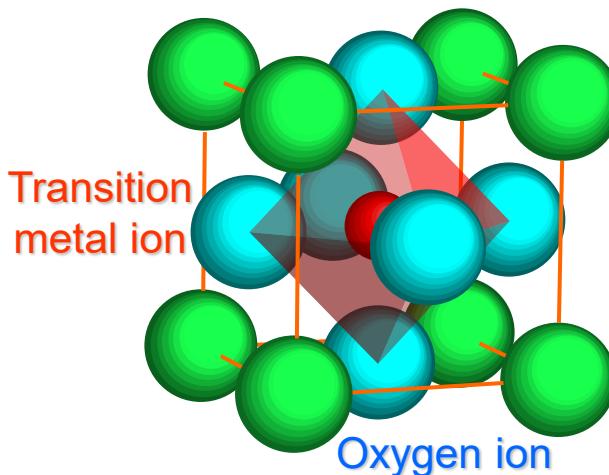
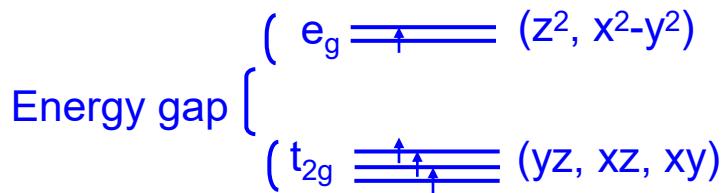
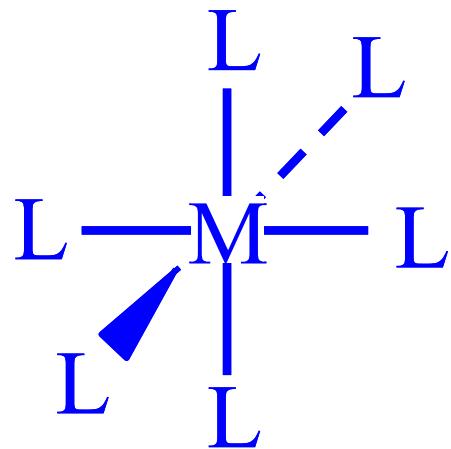
VCH: The international name in scientific publishing

6	6La Lanthanum	6Ce Cerium	6Pr Praseodymium	6Nd Neodymium	6Sm Samarium	6Eu Europium	6Gd Gadolinium	6Tb Thulium	6Dy Dysprosium	6Ho Holmium	6Er Erbium	6Tm Thulium	6Yb Ytterbium	7Lu Lutetium	
7	7Ac Actinium	7Th Thorium	7Pa Protactinium	7U Uranium	7Np Neptunium	7Pu Plutonium	7Am Americium	7Cm Curium	7Bk Berkelium	7Cf Californium	7Es Esmeium	7Fm Fermium	7Md Mendelevium	7Nh Nobelium	7Lr Livermorium



Crystal field splitting of perovskite structure

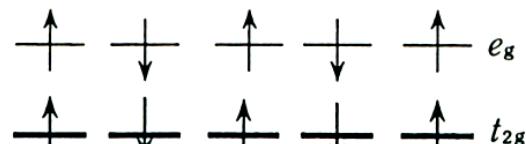
Octahedral ligands



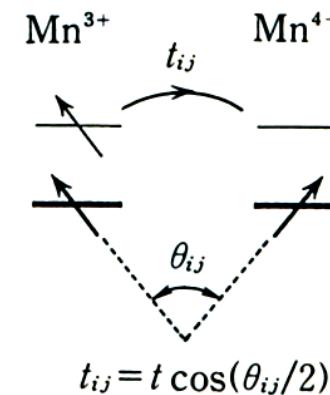
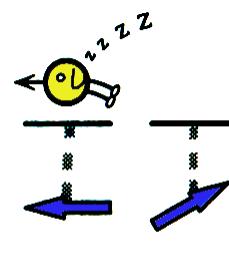
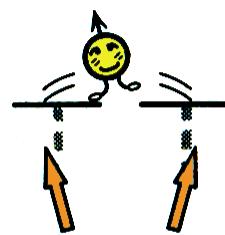
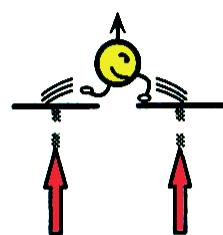
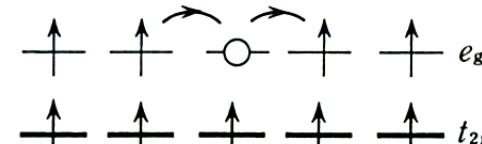
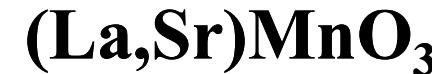


Required interaction for material design

Superexchange interaction



Carrier doping

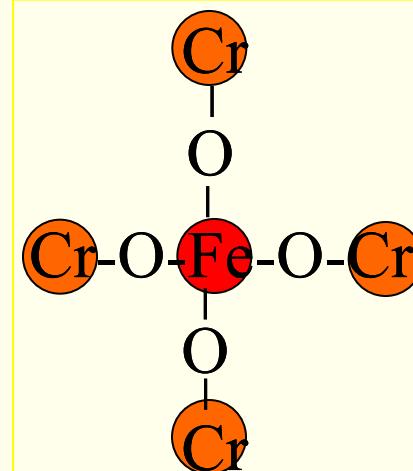
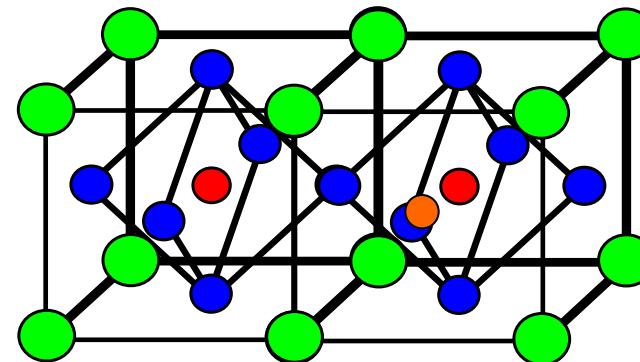
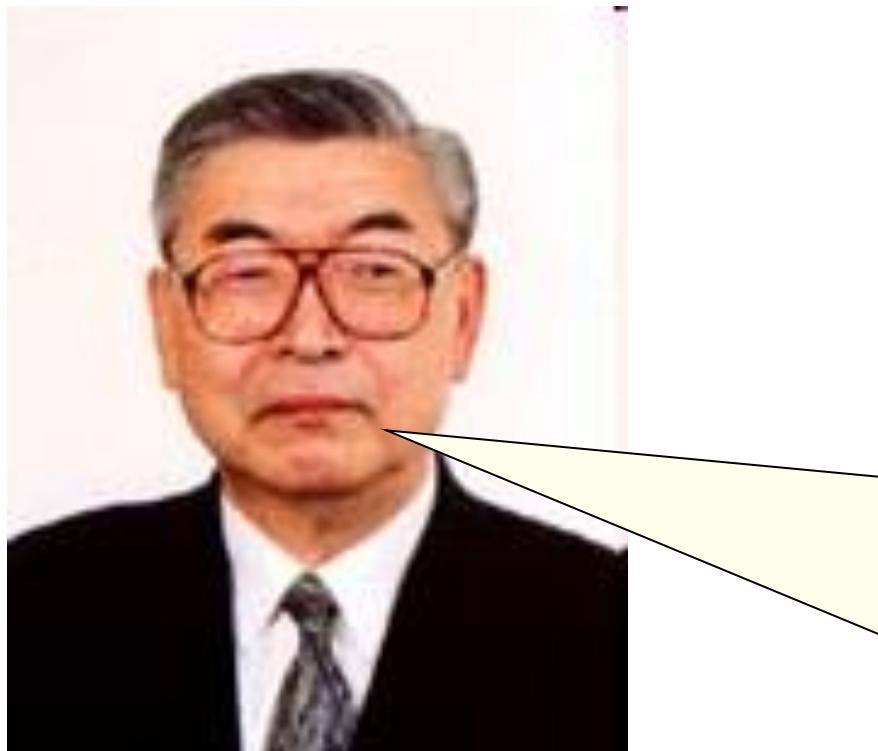


$$H = -t_{\text{Mn-Mn}} \cos\left(\frac{\theta}{2}\right) - K_{\text{Hund}} \sigma S_{\text{Mn}} - J_{\text{t2g}} \sum_{LMnO} S_{\text{Mn}}^{t2g} S_{\text{Mn}}^{t2g}$$



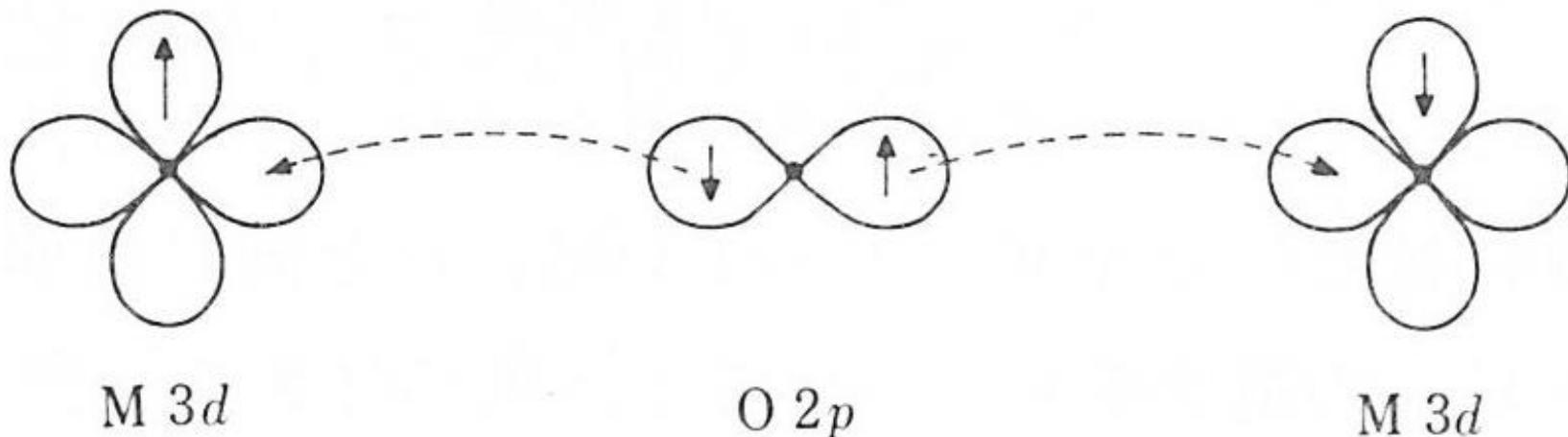
Kanamori-Goodenough rules

Kanamori former
president of Osaka Univ.





Superexchange interaction

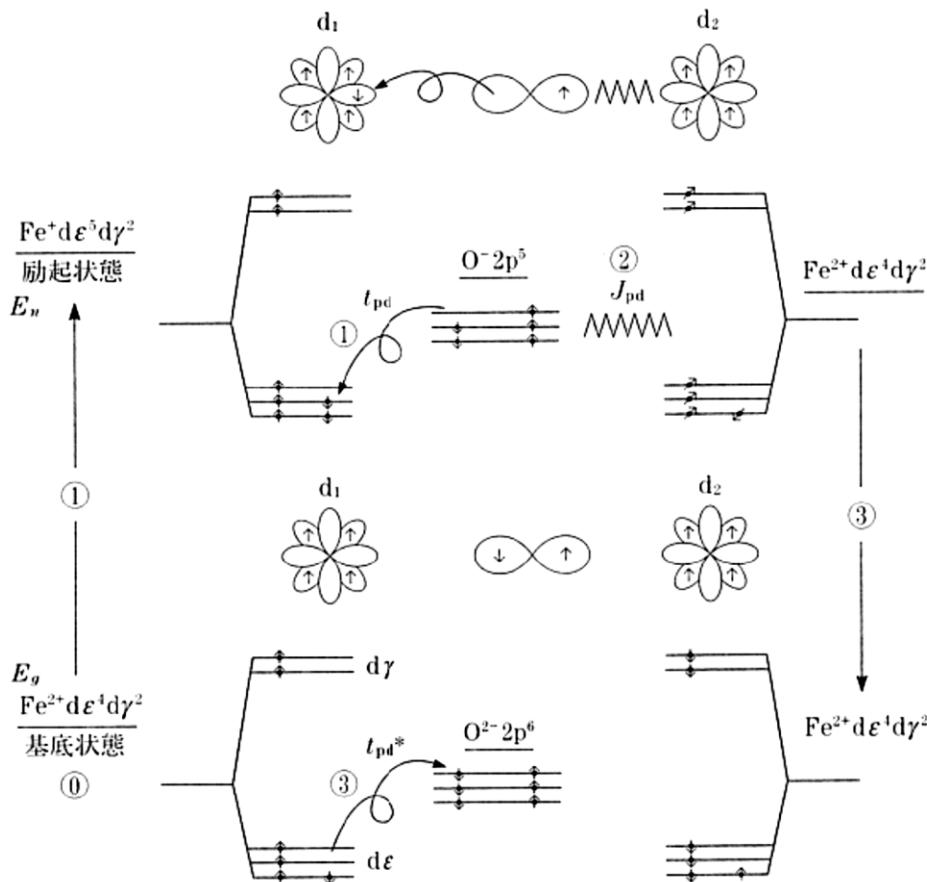


Superexchange interaction

→ Indirect interaction between two magnetic atoms
through non-magnetic atom



Superexchange interaction

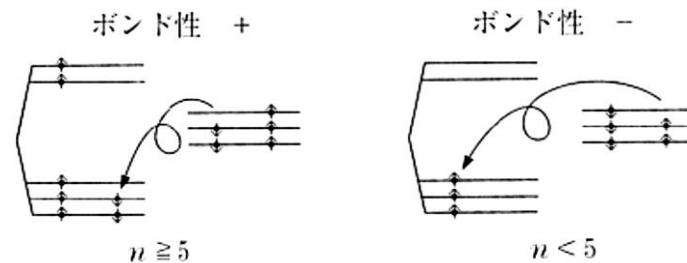


$(3\text{d}^6 - 2\text{p}^6 - 3\text{d}^6)$

Considering an excited state in the case of electron transfer from $2p$ orbital to $3d$ orbital

$$(\text{transfer integral}) \quad t_{pd} = \int \phi_d * V_{pd} \phi_p dr$$

■ bonding rule



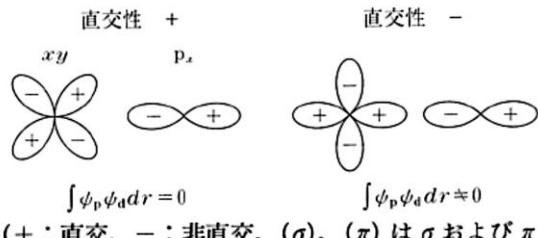
Considering a direct exchange interaction (J_{pd}) between $2p$ spin and $3d$ spin



Superexchange interaction

Sign of J_{pd} Ferromagnetic $J_{pd} > 0$, Antiferromagnetic $J_{pd} < 0$

... Orthogonal character of J_{pd}



直交性 + 直交性 -

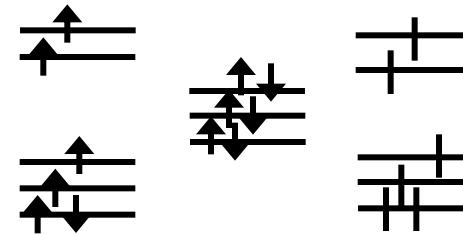
$$\int \psi_p \psi_d dr = 0$$

$$\int \psi_p \psi_d dr \neq 0$$

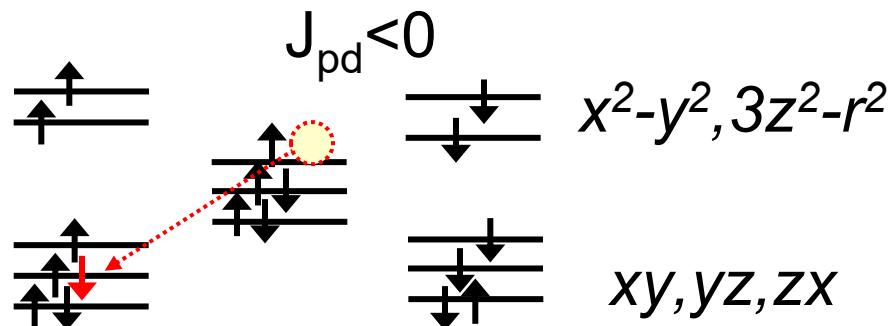
(+ : 直交, - : 非直交, (σ), (π) は σ および π 結合)

d	p_x	p_y	p_z	s
$3z^2 - r^2$	X - (σ)	+	+	- (σ)
	Y +	- (σ)	+	- (σ)
	Z +	+	- (σ)	- (σ)
$x^2 - y^2$	X - (σ)	+	+	- (σ)
	Y +	- (σ)	+	- (σ)
	Z +	+	+	+
xy	X +	- (π)	+	+
	Y - (π)	+	+	+
	Z +	+	+	+
yz	X +	+	+	+
	Y +	+	- (π)	+
	Z +	- (π)	+	+
zx	X +	+	- (π)	+
	Y +	+	+	+
	Z - (π)	+	+	+

Fe²⁺ O²⁻ Fe²⁺



3d⁶ 2p⁶ 3d⁶



Orthogonal character table in case that
d orbital function locates the origin and
s and p orbitals arrange Orthogonal coordinates of X, Y and Z axes

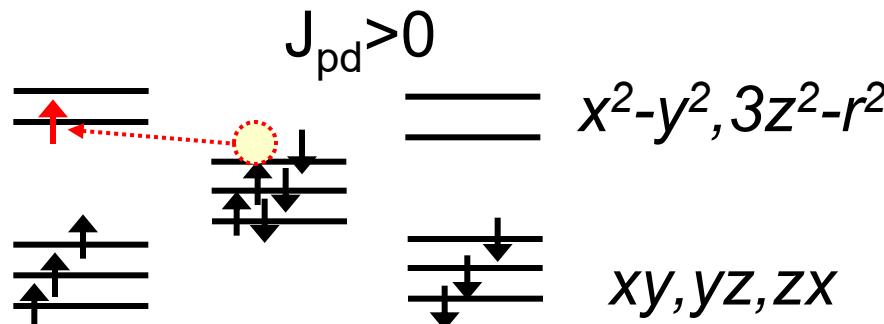
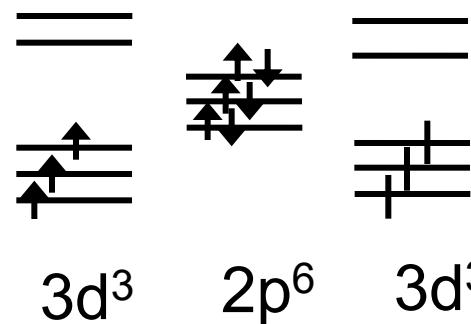
FeO is an antiferromagnetic material



Superexchange interaction

Ex.) Mn⁴⁺ - Mn⁴⁺ : Antiferromagnetic

Mn⁴⁺ O²⁻ Mn⁴⁺



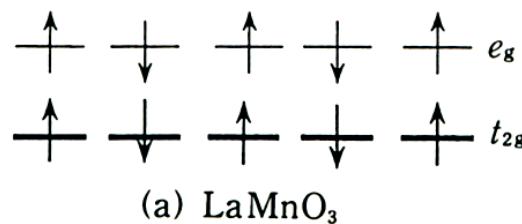
d	p _x	p _y	p _z	s
3z ² - r ²	X Y Z	- (σ) + +	+ - (σ) +	+ - (σ) - (σ)
	X Y Z	- (σ) + +	+ - (σ) +	- (σ) - (σ) +
	X Y Z	- (σ) + +	+ + +	- (σ) - (σ) +
x ² - y ²	X Y Z	+ + +	- (π) + +	+ + +
	X Y Z	+ - (π) +	+ + +	+ + +
	X Y Z	+ + +	+ + +	+ + +
yz	X Y Z	+ + +	+ + - (π)	+ + +
	X Y Z	+ + -	+ - (π) +	+ + +
	X Y Z	+ + - (π)	+ + +	+ + +
zx	X Y Z	+ + - (π)	+ + +	- (π) + +
	X Y Z	+ + -	+ + +	+ + +
	X Y Z	+ + -	- (π) + +	+ + +



Double exchange interaction

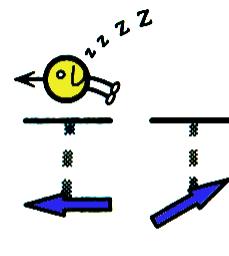
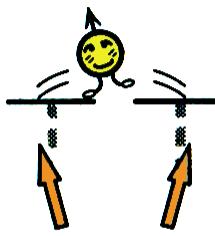
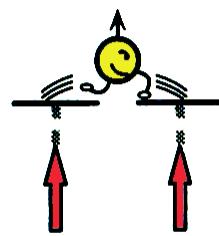
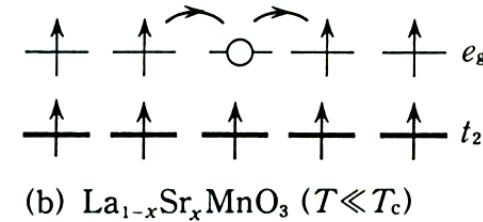
Superexchange interaction

LaMnO_3



Carrier doping

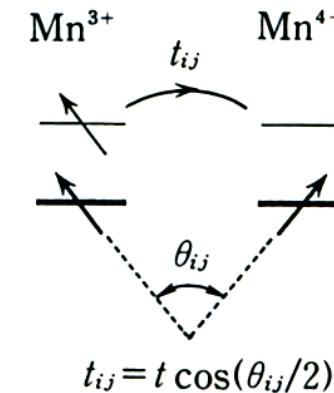
$(\text{La}, \text{Sr})\text{MnO}_3$



(a)

(b)

(c)

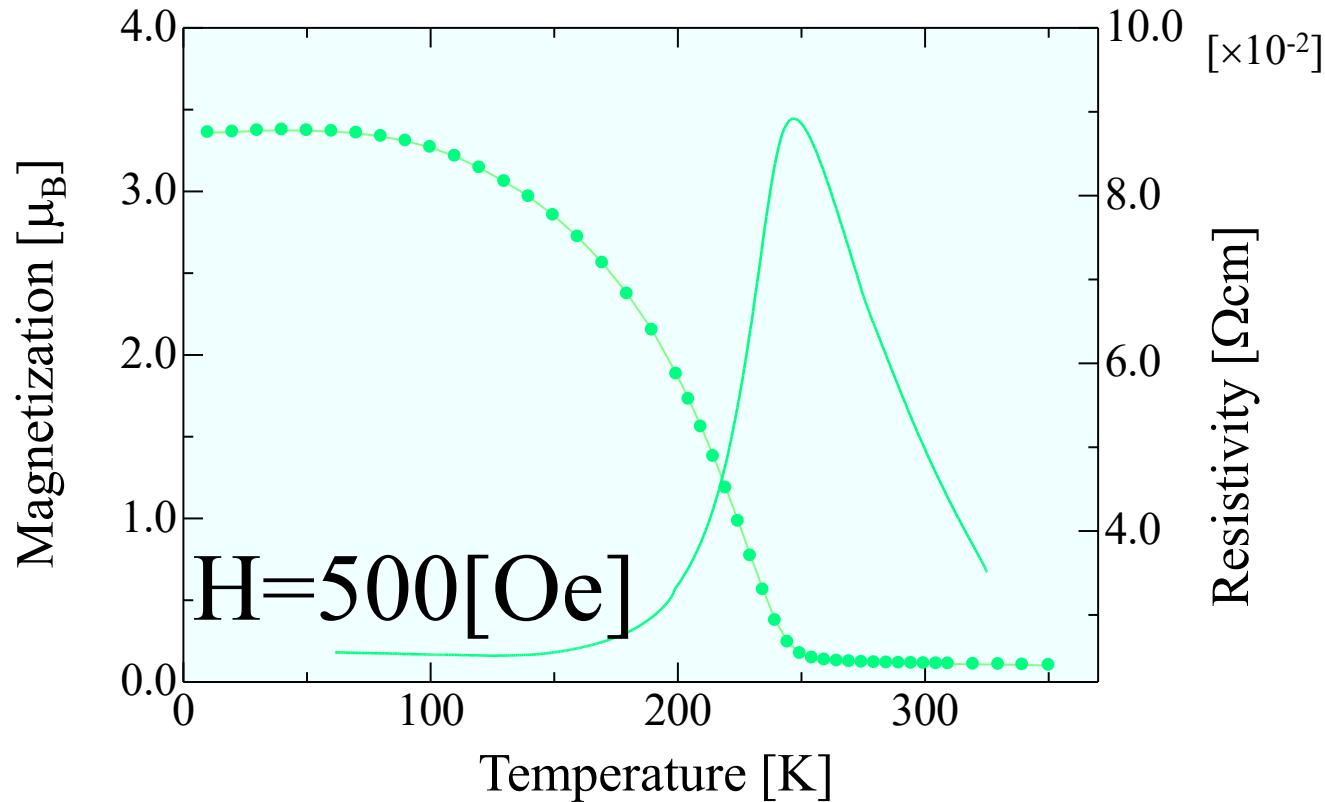


$$H = -t_{\text{Mn-Mn}} \cos\left(\frac{\theta}{2}\right) - K_{\text{Hund}} \sigma S_{\text{Mn}} - J_{\text{t2g}} \sum_{LMnO} S_{\text{Mn}}^{t2g} S_{\text{Mn}}^{t2g}$$



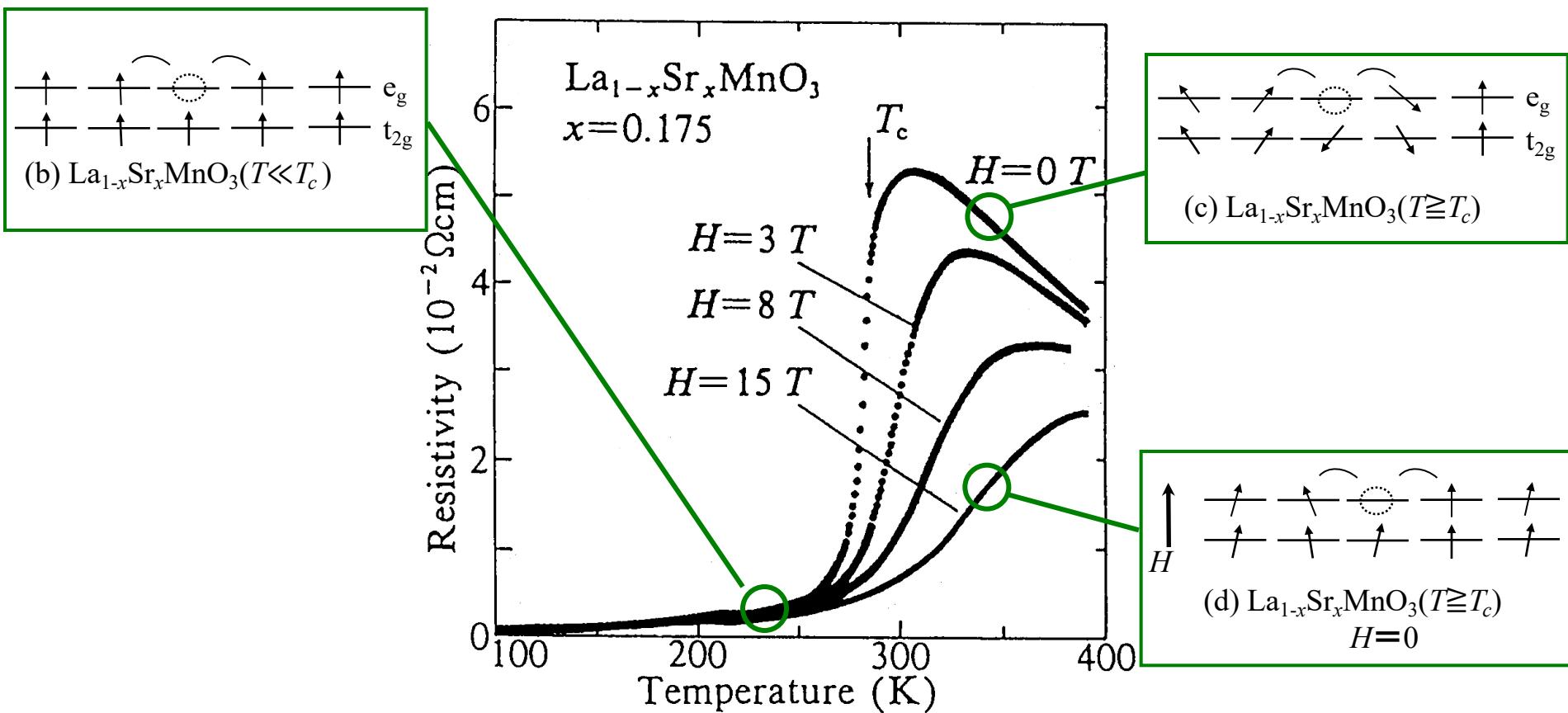
Magnetism modulation due to change of electron transfer integral

$$H = -t_{\text{Mn-Mn}} \cos\left(\frac{\theta}{2}\right) - K_{\text{Hund}} \sigma S_{\text{Mn}} - J_{\text{t2g}} \sum_{LMnO} S_{\text{Mn}}^{t2g} S_{\text{Mn}}^{t2g}$$





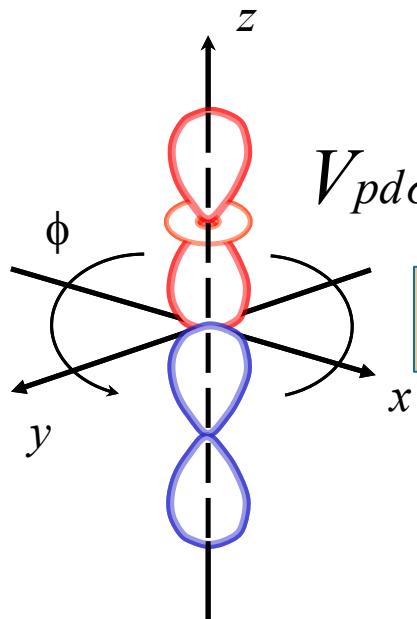
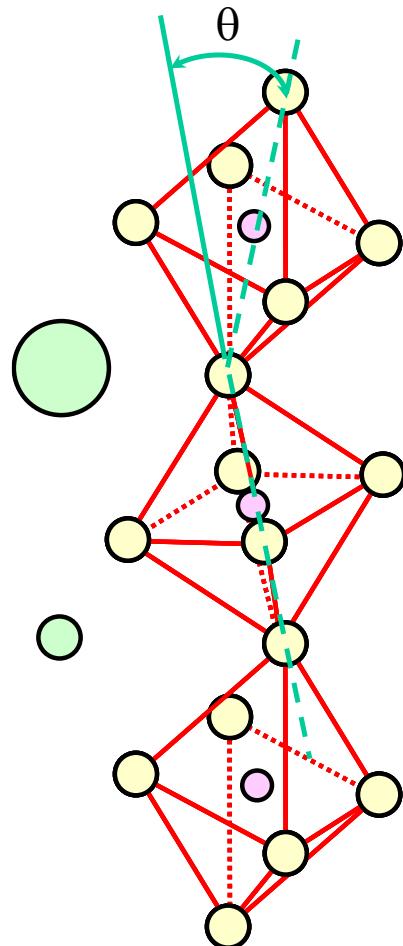
Colossal magneto resistance (CMR)



Temperature dependence of resistivity with a variety of magnetic fields in $\text{La}_{1-x}\text{Sr}_x\text{MnO}_3$ crystal (negative CMR).
 T_c indicates the Curie temperature at $H=0 \text{ T}$.



Main parameters of transfer integral changes



Harrison's equation

$$V_{pd\sigma} = \langle \Phi_d | H | \Phi_p \rangle \sim d^{-7/2}$$

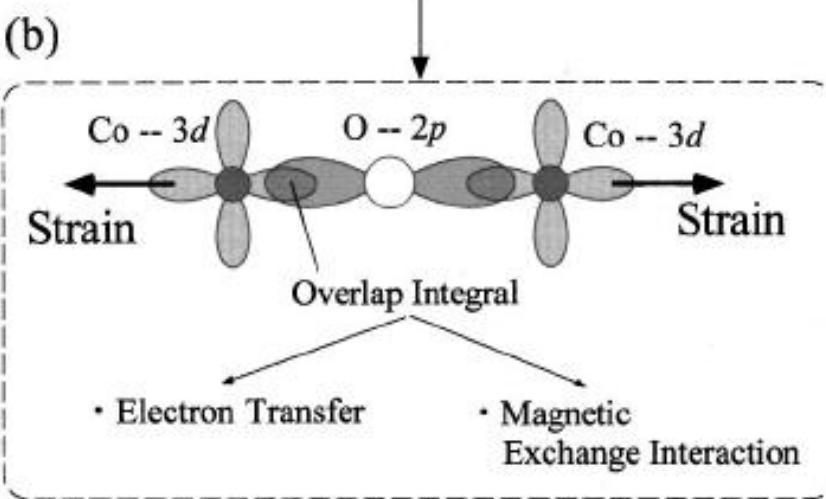
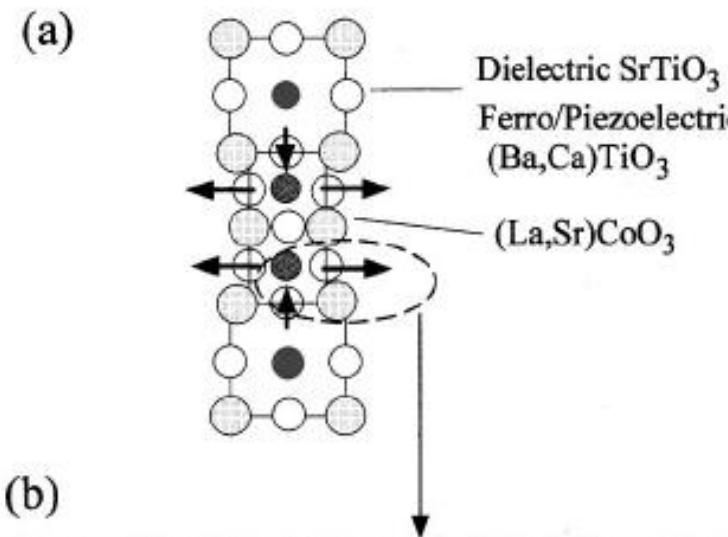
d : the distance between orbitals

ϕ : the bond angle

$$E_{3z^2-r^2, 3z^2-r^2} = \left[n^2 - \frac{1}{2}(l^2 + m^2) \right]^2 V_{dd\sigma} + 3n^2(l^2 + m^2) V_{dd\pi} + \frac{3}{4}(l^2 + m^2)^2 V_{dd\delta}$$
$$\approx \cos \phi$$



Main parameters of transfer integral changes



Tensile strain

$$V_{pd\sigma} \sim d^{-7/2}$$

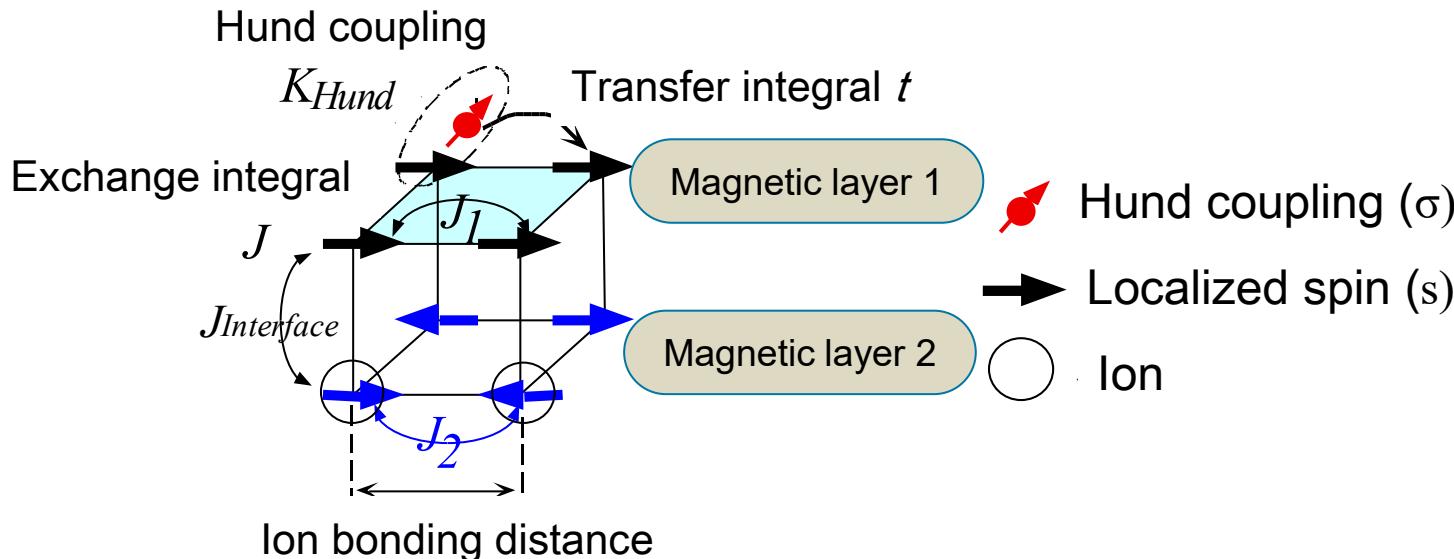
Compressive strain

Band width $W = 2zV$

z : Coordination number



Material design for oxide spintronics



d electron energy Coulomb integral Hund coupling Exchange integral

$$H_{electron} = \sum E_d + \frac{1}{2} \sum U + K_{Hund} \sum_i \sigma S_i + \sum_{i,j} J_{ij} S_i S_j$$
$$+ \sum E_p + \sum t + A \sum_i d Q d$$

Transfer integral



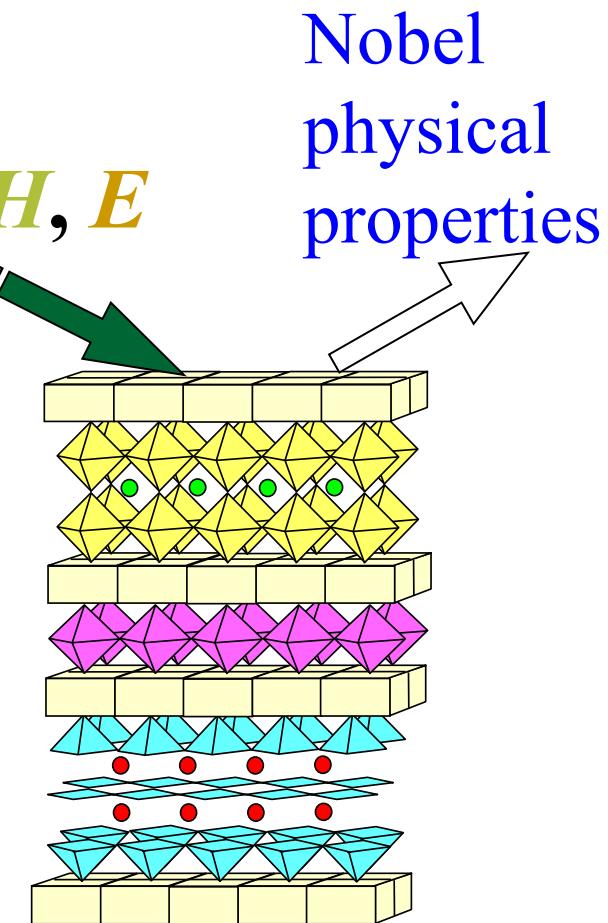
Material design for oxide spintronics

(1) Introduce strain effect

$h\nu, H, E$

(2) Introduce magnetic interaction
between different layers

(3) Integrate different functional
materials

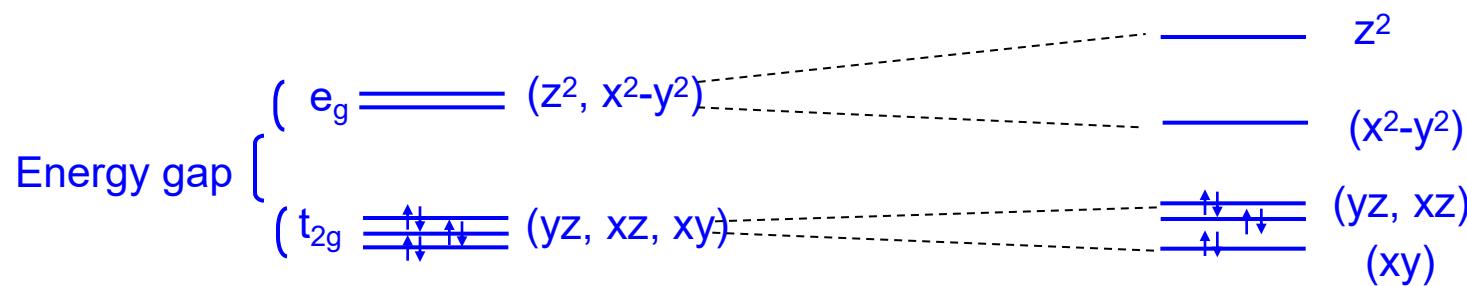
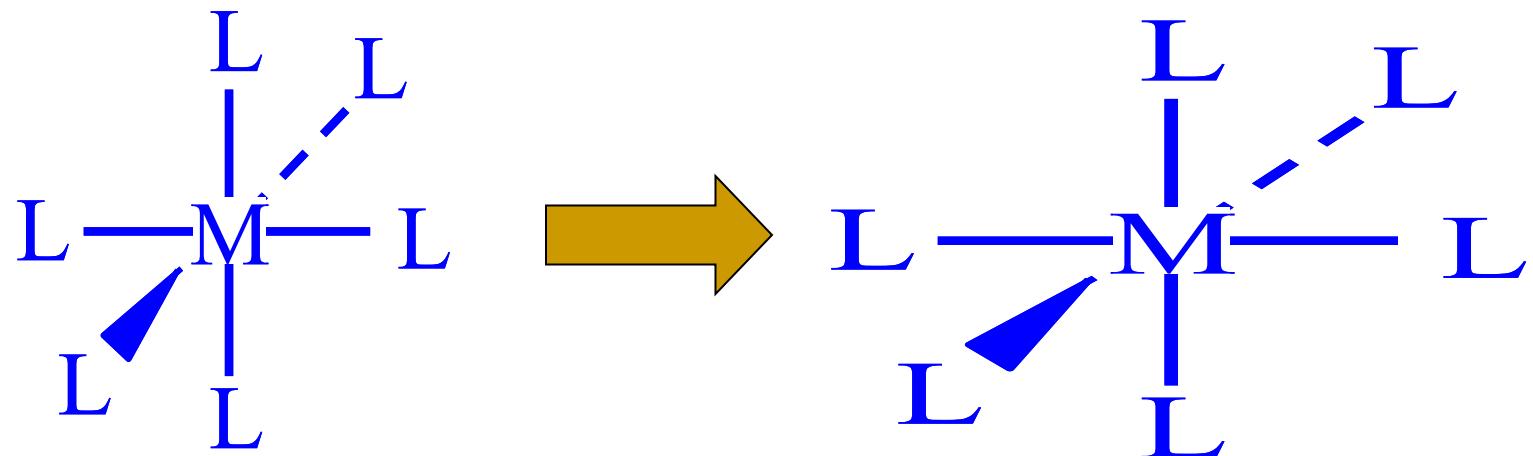




Control of crystal field splitting due to strain effect

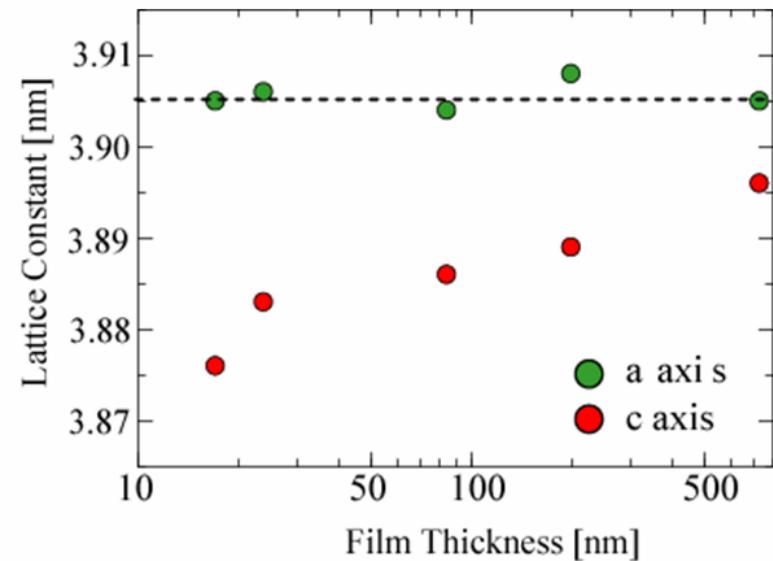
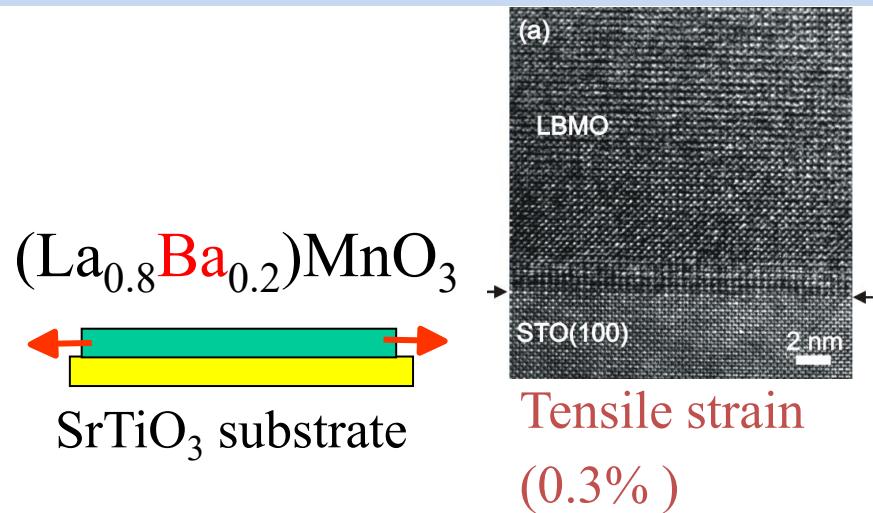
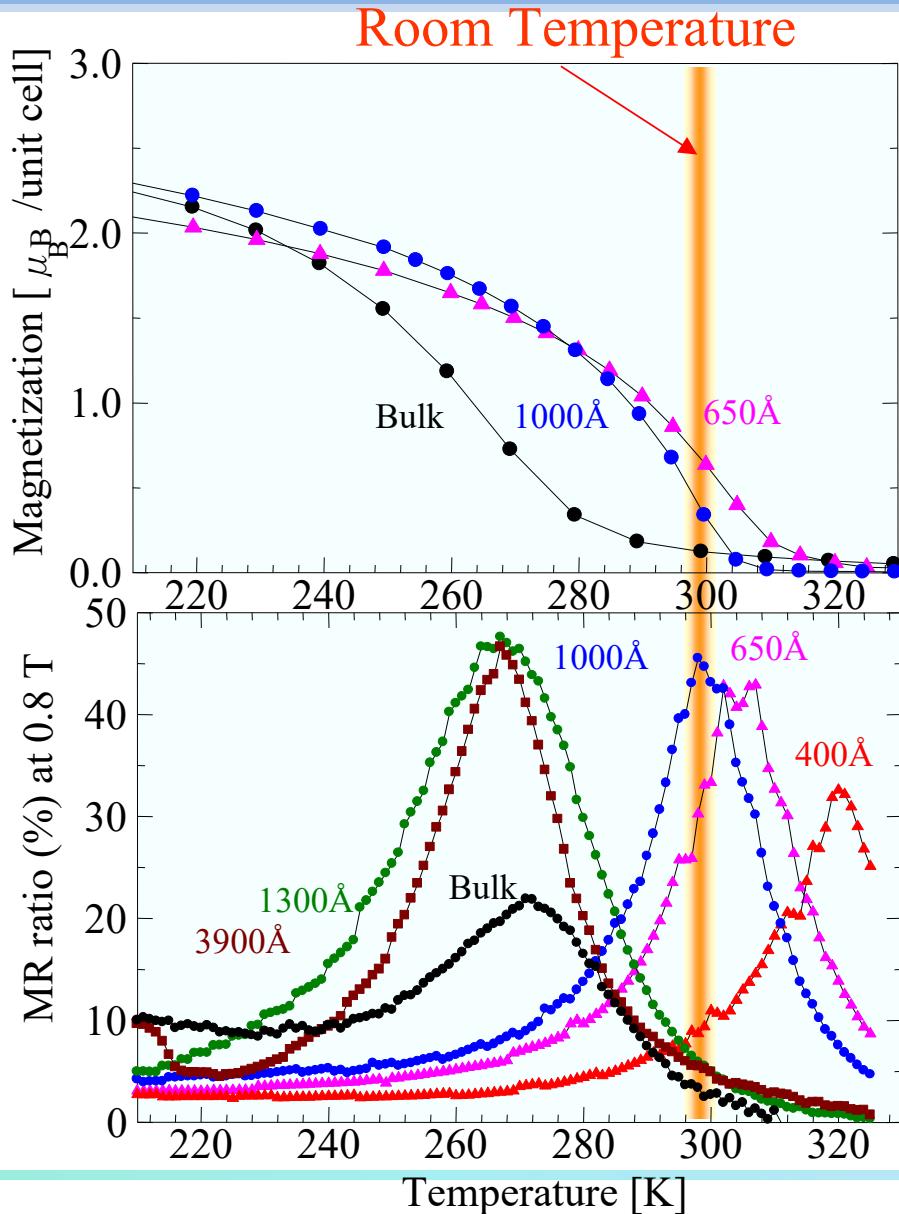
Octahedral coordination

In-plane tensile strain



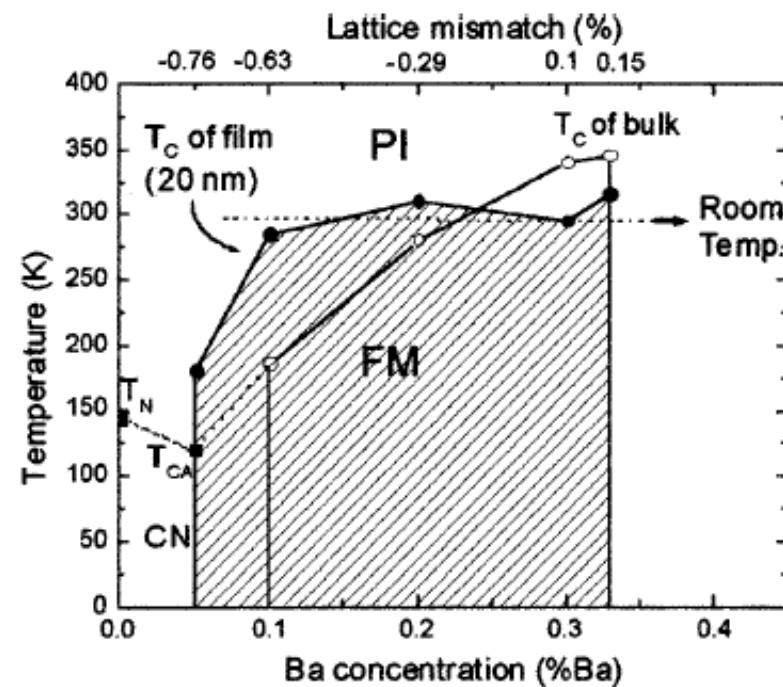
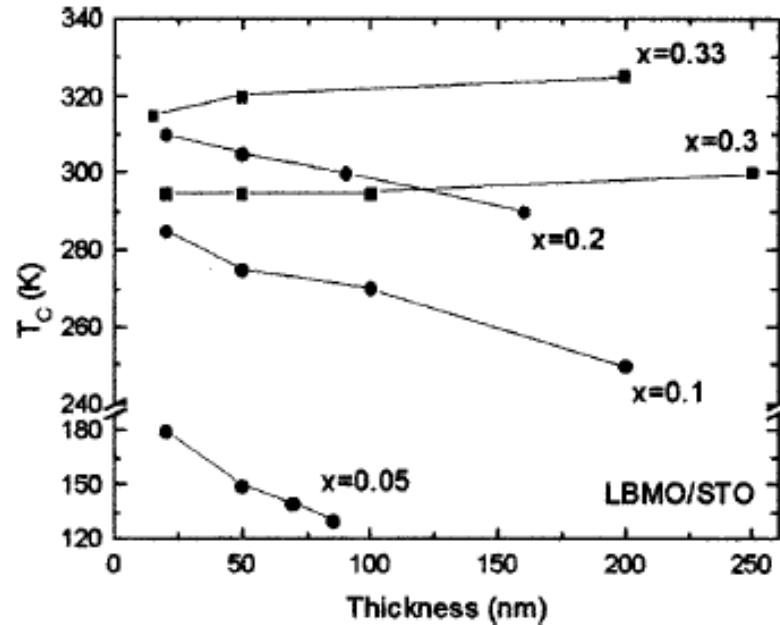


Design of room temperature CMR materials





Strain effect vs T_C in LBMO films



Tensile strain \leftarrow



Compressive strain \rightarrow



x	0.05	0.1	0.2	0.3	0.33
Lattice mismatch (%)	-0.76	-0.63	-0.29	0.1	0.15
Strain type	T	T	T	C	C
T_C of bulk (K)	120 ^a	185	280	340	345
T_C of film (20 nm) (K)	180	285	310	290	315

Increase in T_C decrease in T_C

Phys. Rev. B 64, 184404(2001)

^aFor $x = 0.05$, spin canting transition temperature $T_{CA} = 120$ K.



Stability of double exchange magnetism

Stability of magnetism induced by double exchange interaction

$$\Delta\epsilon_{ex}^D = zxt_{ij} = zx b_\sigma \langle \cos(\theta_{ij}/2) \rangle$$

C. Zener: Phys. Rev. **82** (1951) 403

P. W. Anderson and H. Hasegawa: Phys. Rev. **100** (1955) 675

P. G. de Gennes: Phys. Rev. **118** (1960) 141

- Z: the coordination number of nearest neighbor atoms ; Z=6
- t_{ij} : the transfer energy
- θ_{ij} : the spin angle between Mn_i and Mn_j

Main parameters indicating the stability of double exchange magnetism

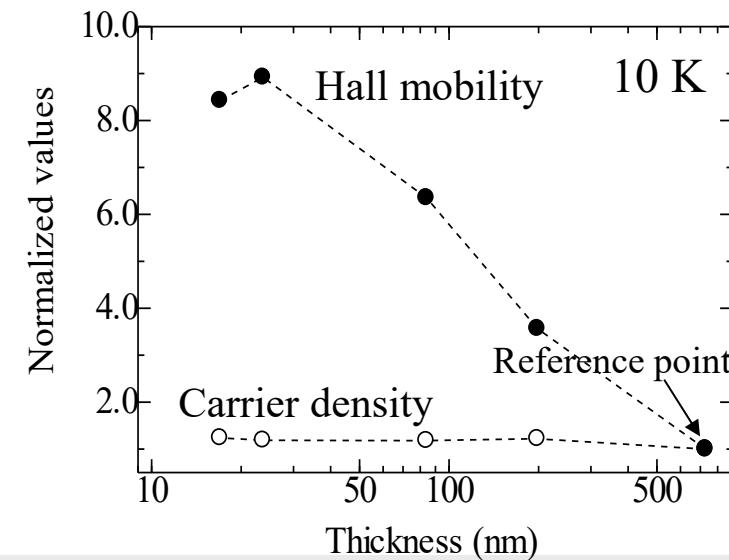
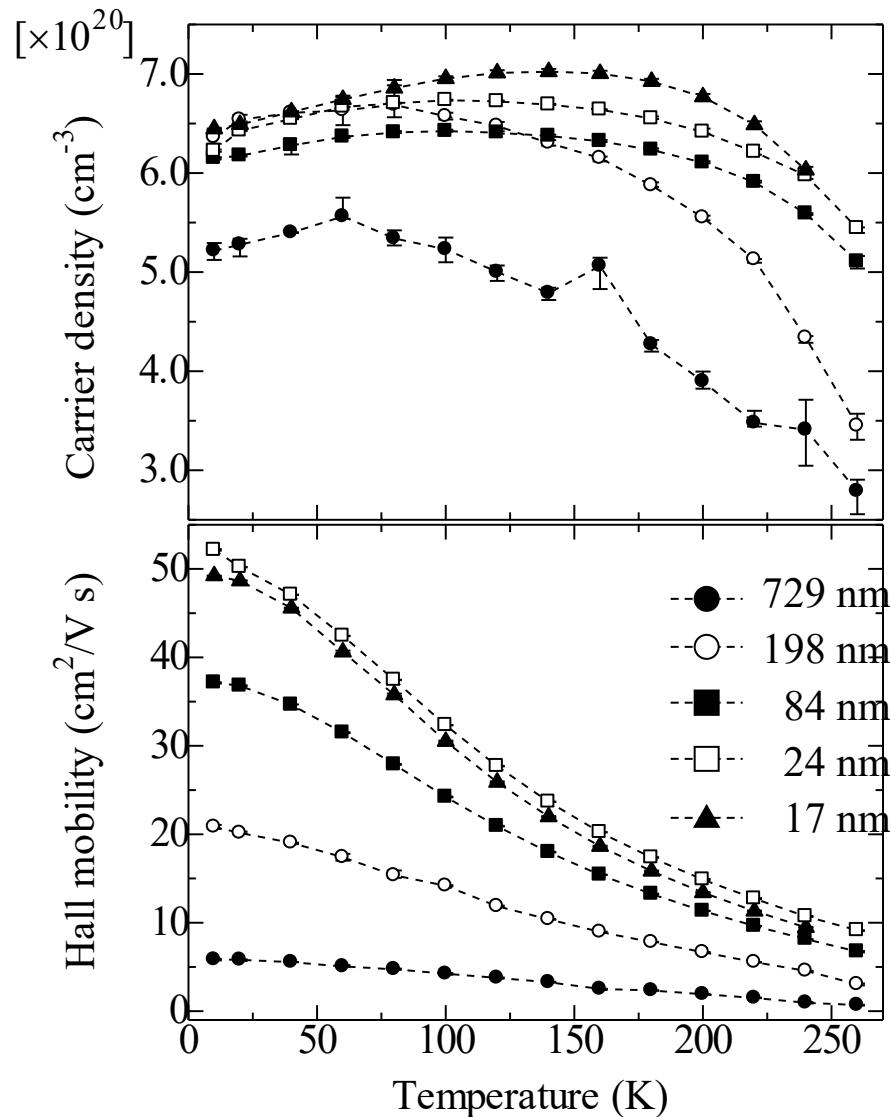
x : the number of carriers per a Mn site

b_σ : Spin-independent components

(dependence of orbital overlap and bond angle of Mn-O-Mn)



Carrier density and Hall mobility



Carrier density : Constant

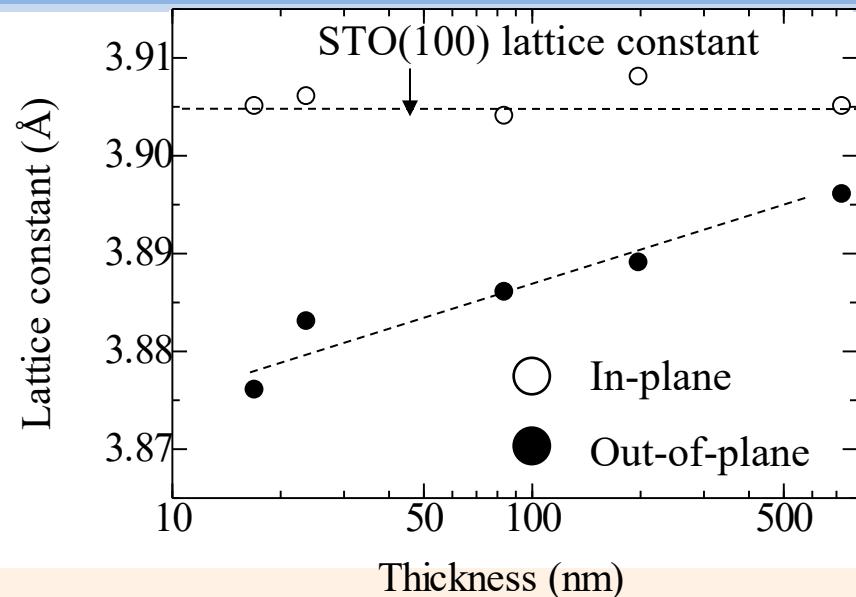
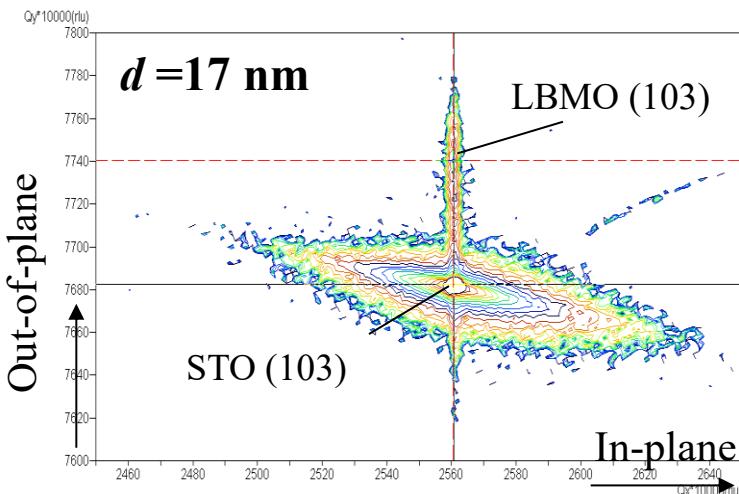
- the number of carrier x : constant
- **Not generating cation deficiency**

Hall mobility : Increase

- Increase in transfer integral
- **change in orbital overlap state due to lattice strain effect**



Stability of transfer integral due to lattice strain effect



Calculation of stability in double exchange interaction
every thickness

◆ stability of double exchange interaction

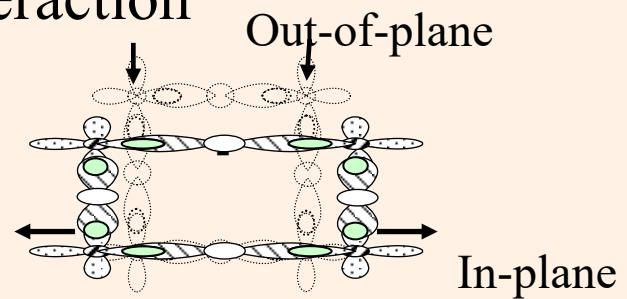
$$\Delta\epsilon_{ex}^D = z\Delta x \Delta t_{ij} \propto \Delta x \Delta b_\sigma \propto \Delta b_\sigma$$

x : the number of carriers per a Mn site

b_σ : Spin-independent components

(dependence of orbital overlap and bond angle of Mn-O-Mn)

Z: the coordination number of nearest neighbor atoms ; Z=6





Contribution elements of stability in double exchange interaction

1. In-plane and Out-of-plane orbital overlap

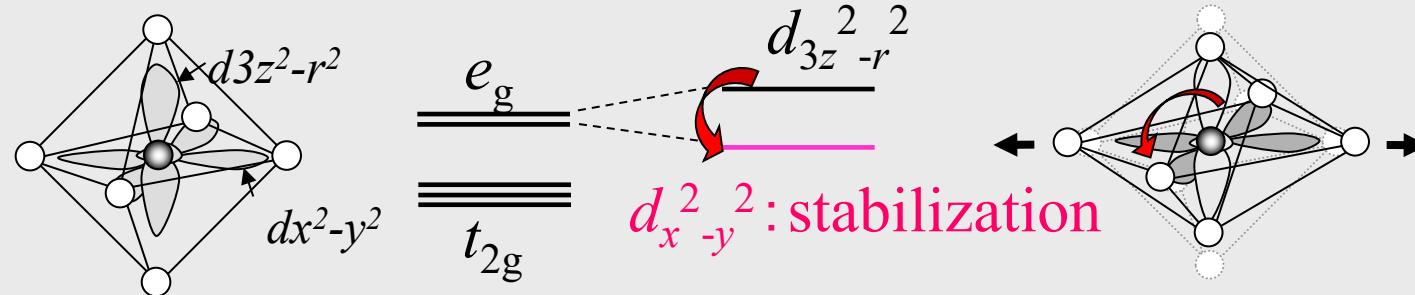
→ determination from lattice constants obtained by experiments

matrix element between p and d orbitals: $V_{pd} = d_{\text{Mn-O}}^{-7/2}$

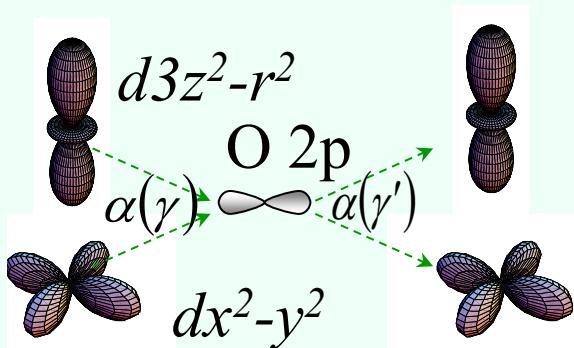
Mn-O-Mn bond angle: 180°

2. Redistribution of e_g electrons due to lattice strain effect → calculation by the DV-X α method

Tensile strain



3. Anisotropy of d orbital



Transfer strength	Out-of-plane		In-plane	
$\gamma \backslash \gamma'$	$ x^2 - y^2\rangle$	$ 3z^2 - r^2\rangle$	$ x^2 - y^2\rangle$	$ 3z^2 - r^2\rangle$
$ x^2 - y^2\rangle$	0	0	$\frac{3}{4}$	$\frac{\sqrt{3}}{4}$
$ 3z^2 - r^2\rangle$	0	1	$\frac{\sqrt{3}}{4}$	$\frac{1}{4}$

Phys. Rev. B 64, 224418(2001)

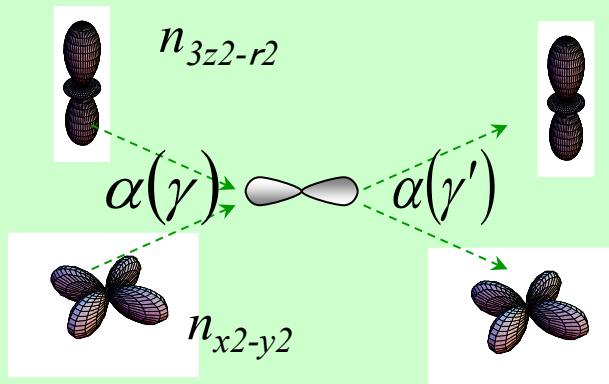


Contribution elements of stability in double exchange interaction

Stability of averaged double exchange interaction

$$\Delta\epsilon_{ex}^D \propto \sum_{*,j>} (n_{x^2-y^2}, n_{3z^2-r^2}, \alpha(\gamma_i)\alpha(\gamma'_j), d_{in}^{-7}, d_{out}^{-7})*$$

Transfer strength from Mn3d orbital to O2p orbital $\alpha(\gamma)$
Transfer strength from O2p orbital to Mn3d orbital $\alpha(\gamma')$



In-plane: 4 directions

Out-of-plane : 2 directions

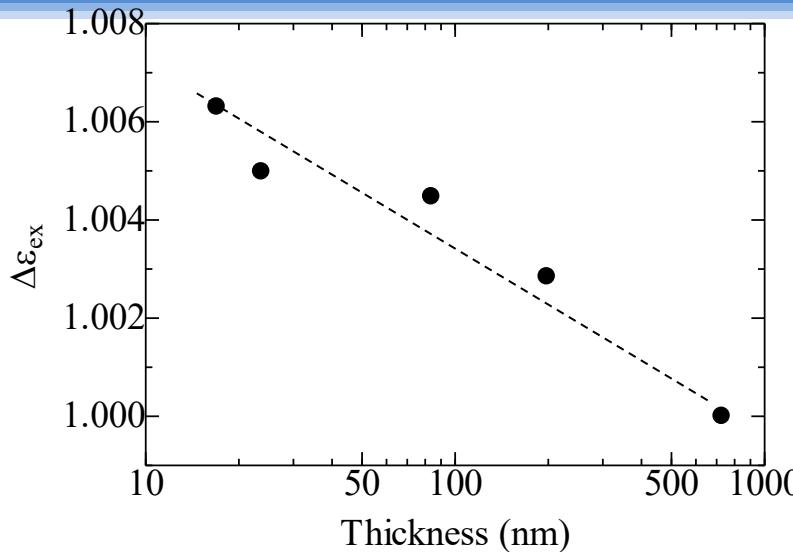
d_{in} : the in-plane Mn-O length
 d_{out} : the out-of-plane Mn-O length
→ derived by XRD measurement

$n_{x^2-y^2}$: the ration of occupied electrons in $d_{x^2-y^2}$ orbital
 $n_{3z^2-r^2}$: the ration of occupied electrons in $d_{3z^2-r^2}$ orbital
→ calculation by the DV-Xα method using experimental lattice constants

$$\Delta\epsilon_{ex}^D \propto ((3 + \sqrt{3})n_{x^2-y^2} + (1 + \sqrt{3})n_{3z^2-r^2})d_{in}^{-7} + 2n_{3z^2-r^2}d_{out}^{-7}$$



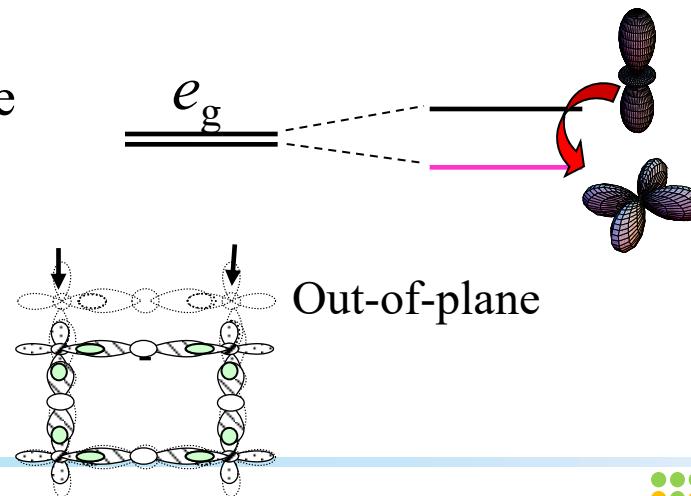
Stability of double exchange magnetism



Stabilization of double exchange interaction with decreasing film thickness

What are main factors of T_C increase in strained $(\text{La},\text{Ba})\text{MnO}_3$ thin films

- ◆ redistribution effect by e_g electrons due to anisotropy d orbital.
- ◆ Orbital overlap of in-plane and out-of-plane





Function of interface

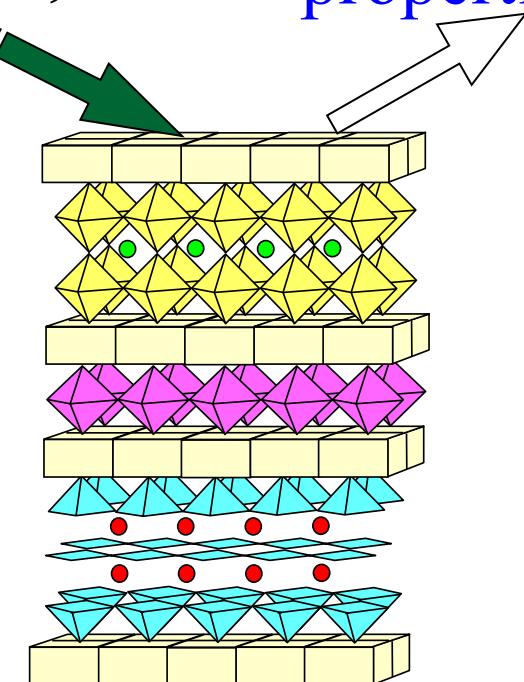
(1) Introduce strain effect

(2) Introduce magnetic interaction
between different layers

(3) Integrate different functional
materials

Nobel
physical
properties

$h\nu, H, E$





Control of interface magnetic interaction

Conductive electron

$$H = -t_{\text{Mn-Mn}} \cos\left(\frac{\theta}{2}\right) - K_{\text{Hund}} \sigma S_{\text{Mn}}$$

Localized spin

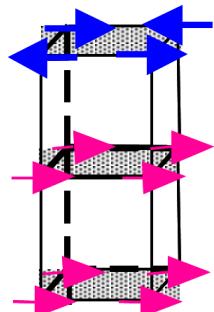
$$- J_{\text{t}2g} \sum_{LMnO} S_{\text{Mn}}^{t2g} S_{\text{Mn}}^{t2g}$$

$$- J_{\text{Fe-Mn}} S_{\text{Mn}}^{t2g} S_{\text{Fe}}$$

$$- \sum_{LFeO} J_{\text{Fe-Fe}} S_{\text{Fe}} S_{\text{Fe}}$$

Antiferromagnet LaFeO_3

Interface magnetic
interaction

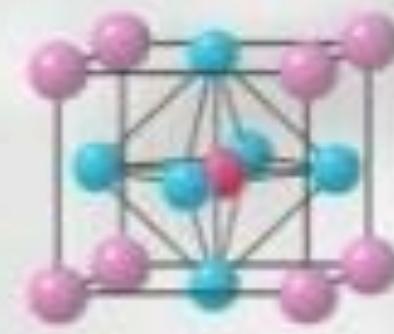


Combined with two materials
⇒ Magnetic susceptibility increases

Ferromagnet $(\text{La},\text{Sr})\text{MnO}_3$



Spin frustration superlattice

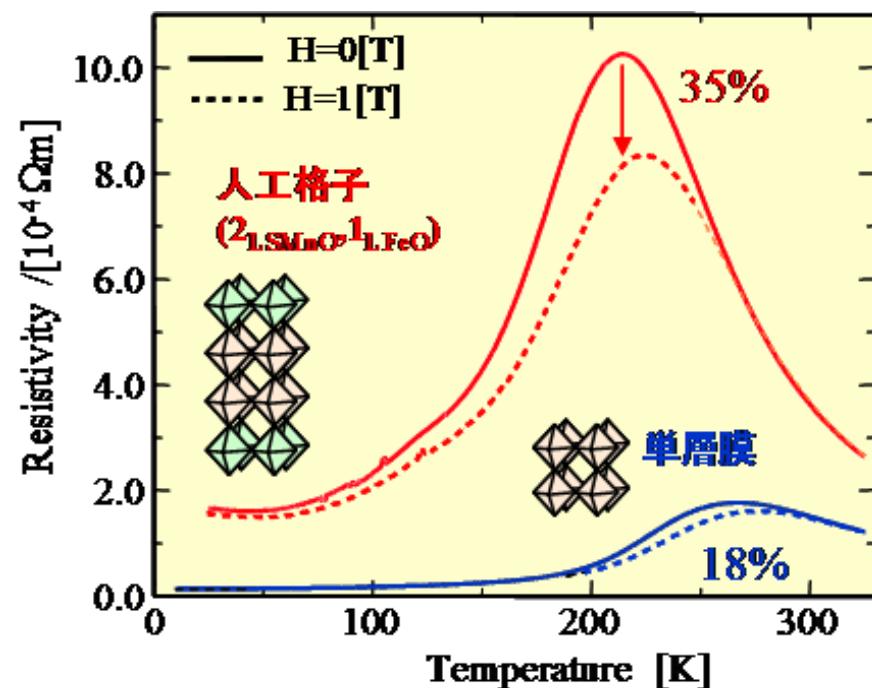
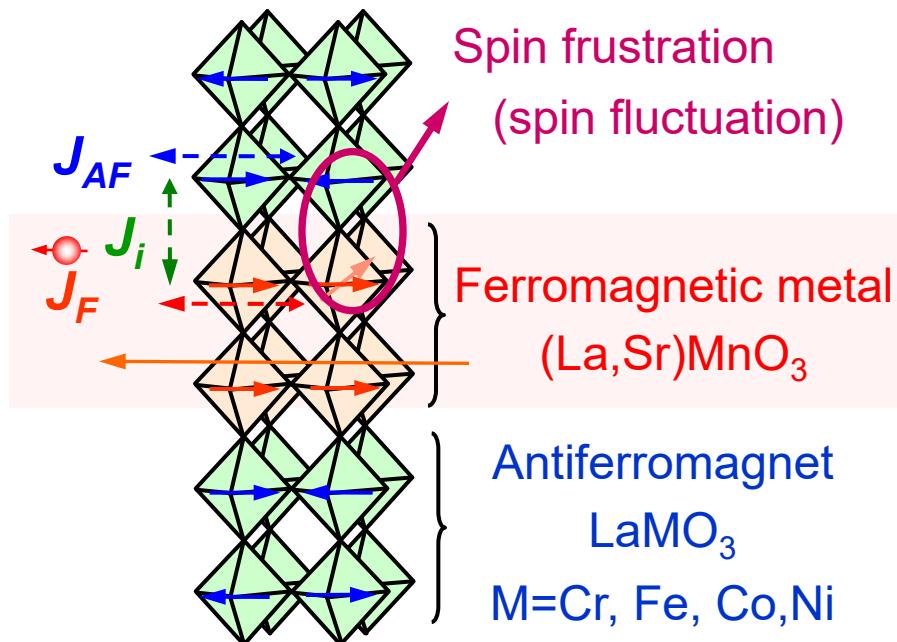


2006)



High sensitive response by magnetic field

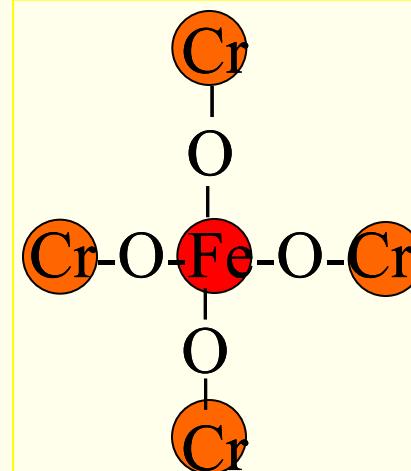
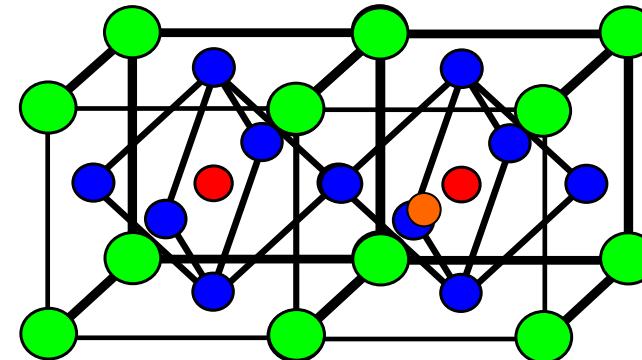
Spin frustration superlattice





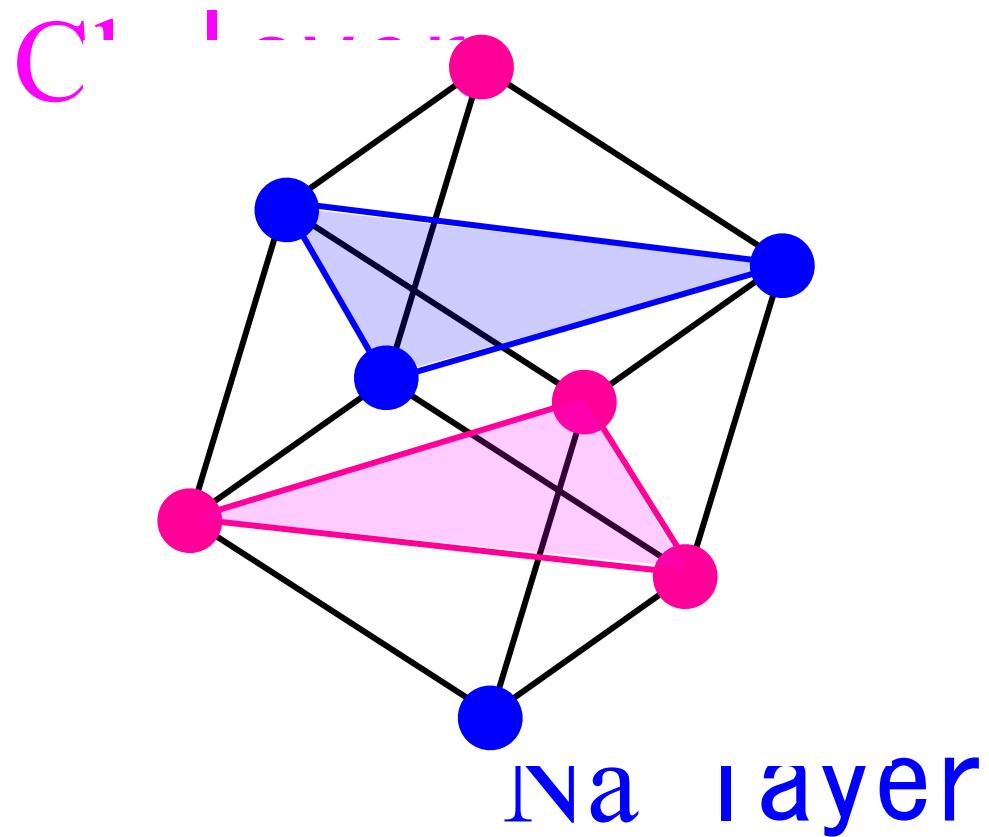
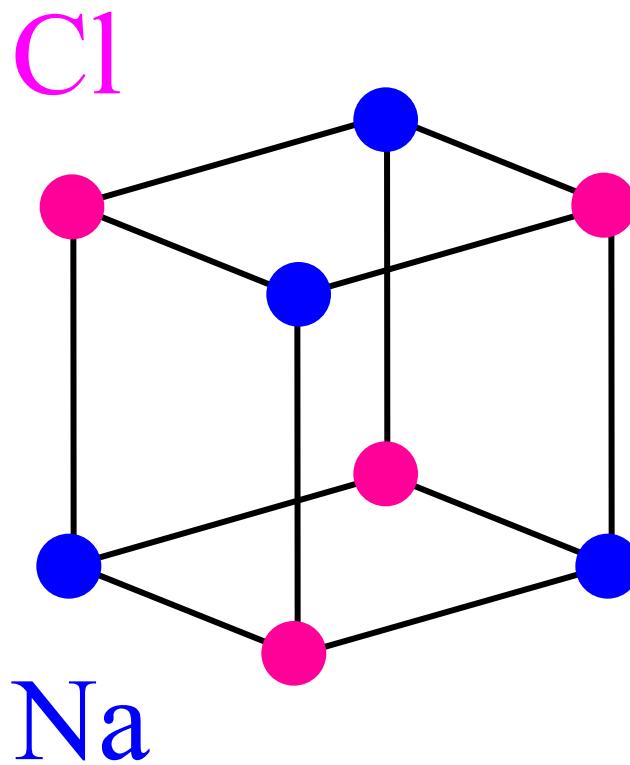
Theoretical prediction : New ferromagnet

Kanamori former
president of Osaka Univ.



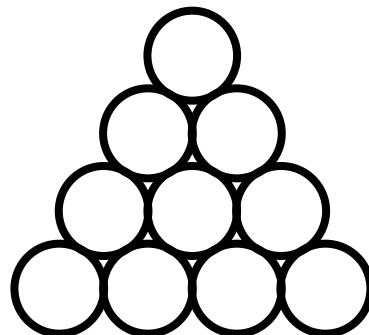


NaCl structure

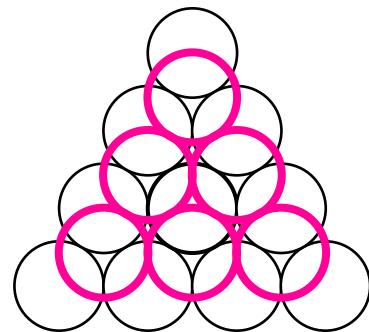




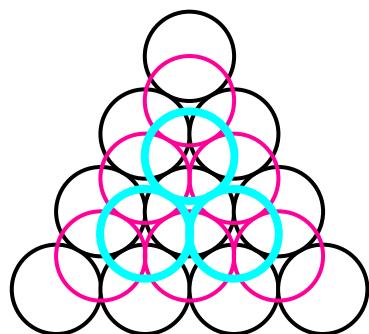
Lattice-direction control superlattice



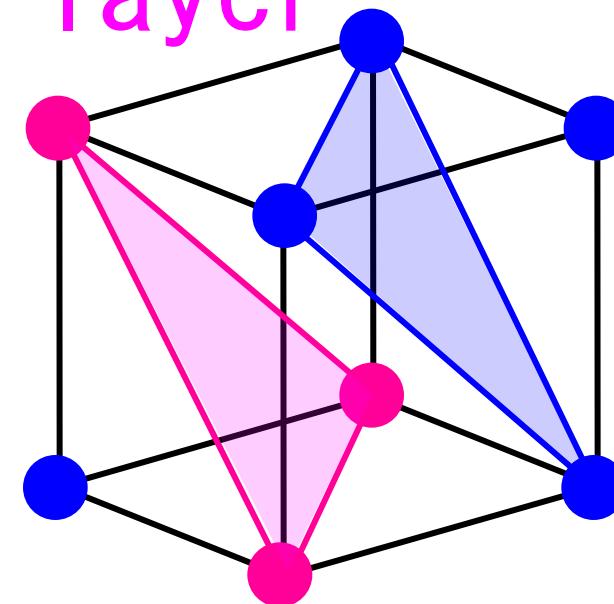
ooooo
1st layer



ooooo
2nd layer



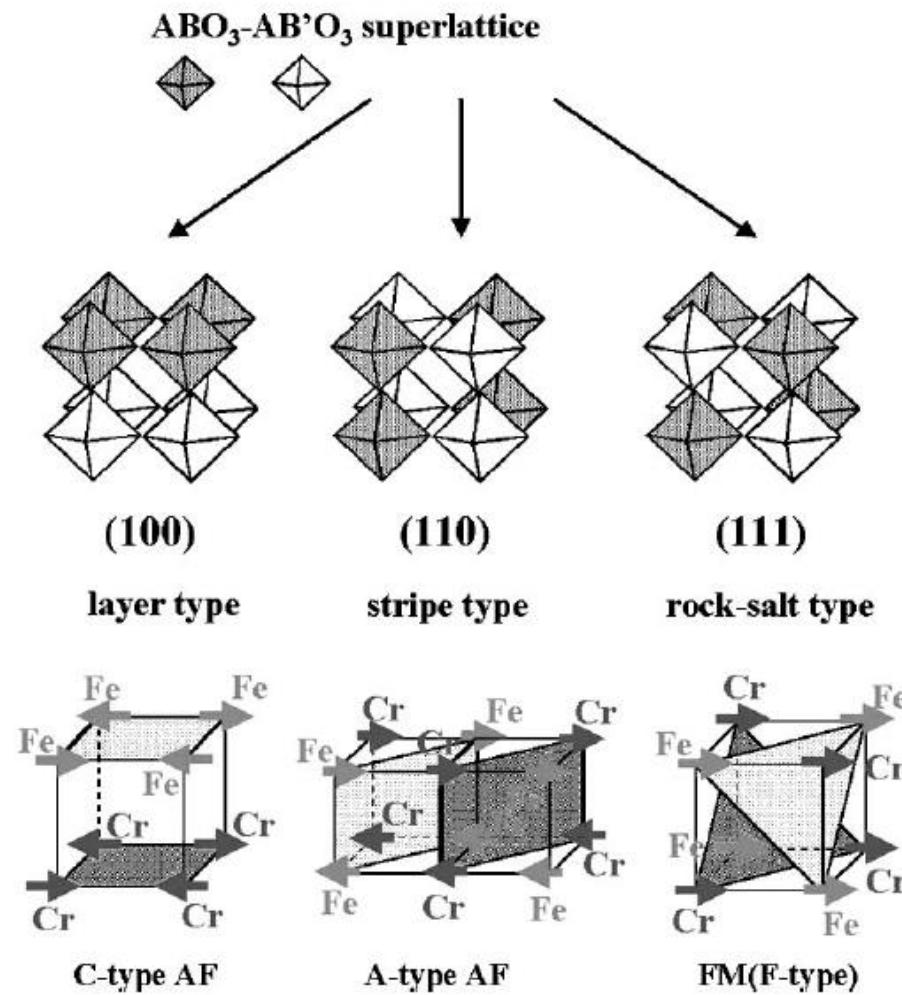
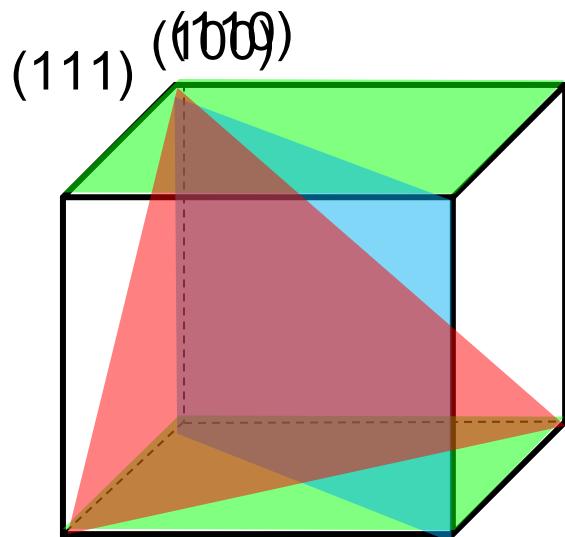
ooo
3rd layer



Cl layer
Na layer



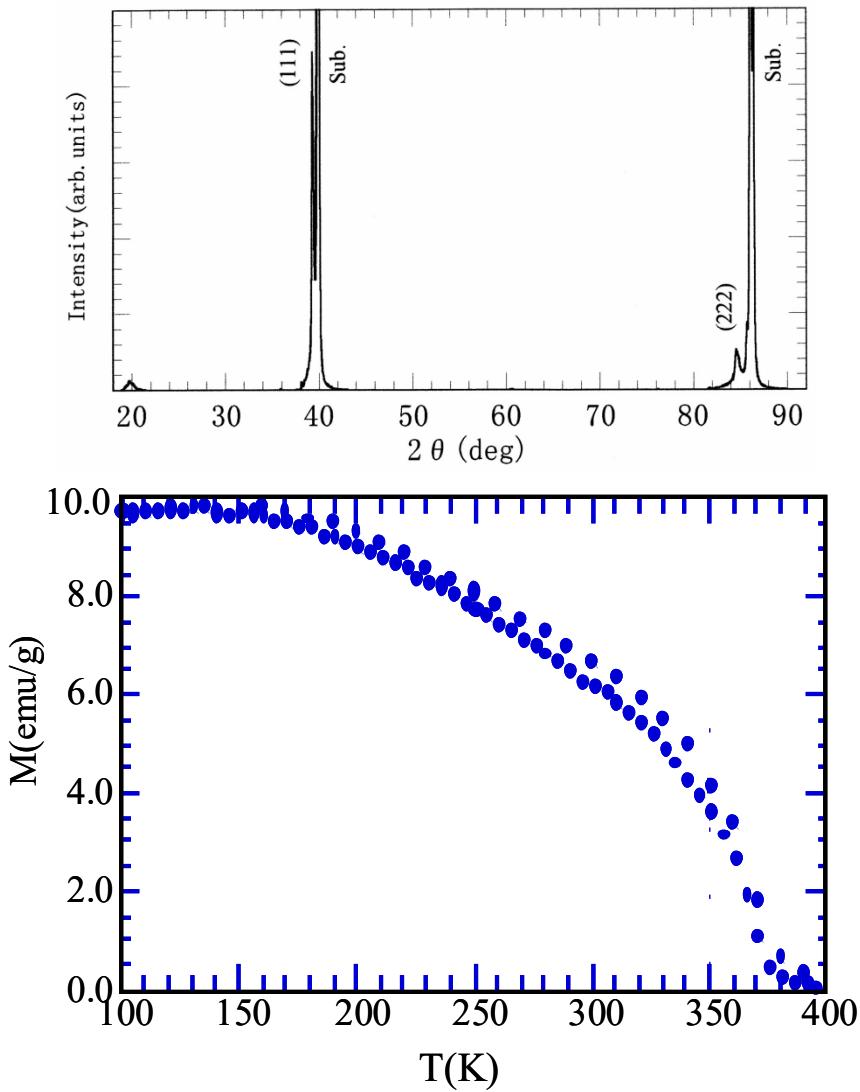
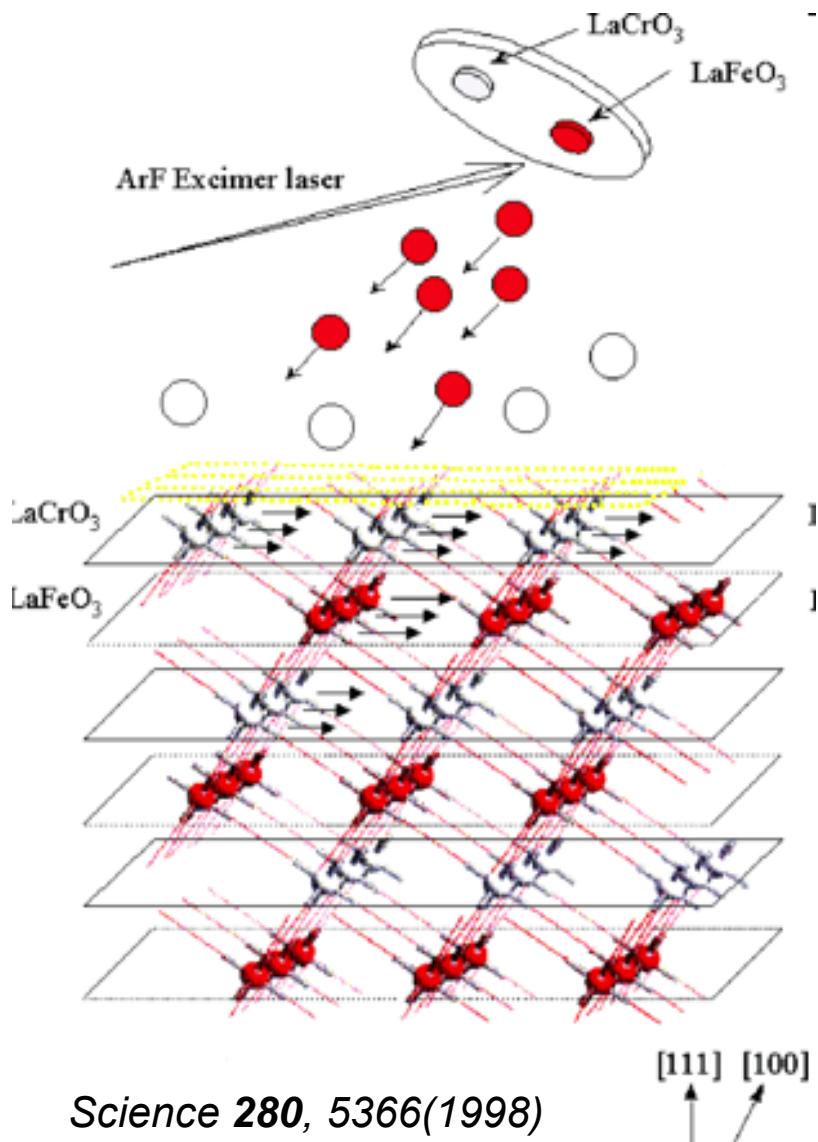
Lattice-direction control superlattice



J. Appl. Phys. **89**, 2847(2001)



Lattice-direction control superlattice





Integration of different functional materials

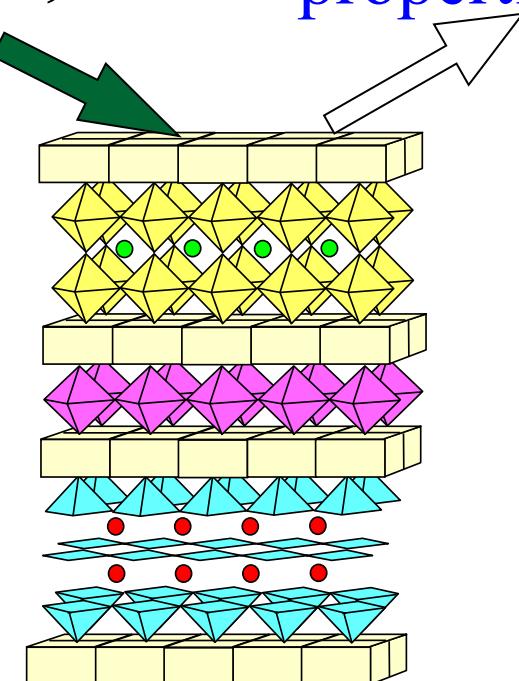
(1) Introduce strain effect

(2) Introduce magnetic interaction
between different layers

(3) Integrate different functional
materials

Nobel
physical
properties

$h\nu, H, E$

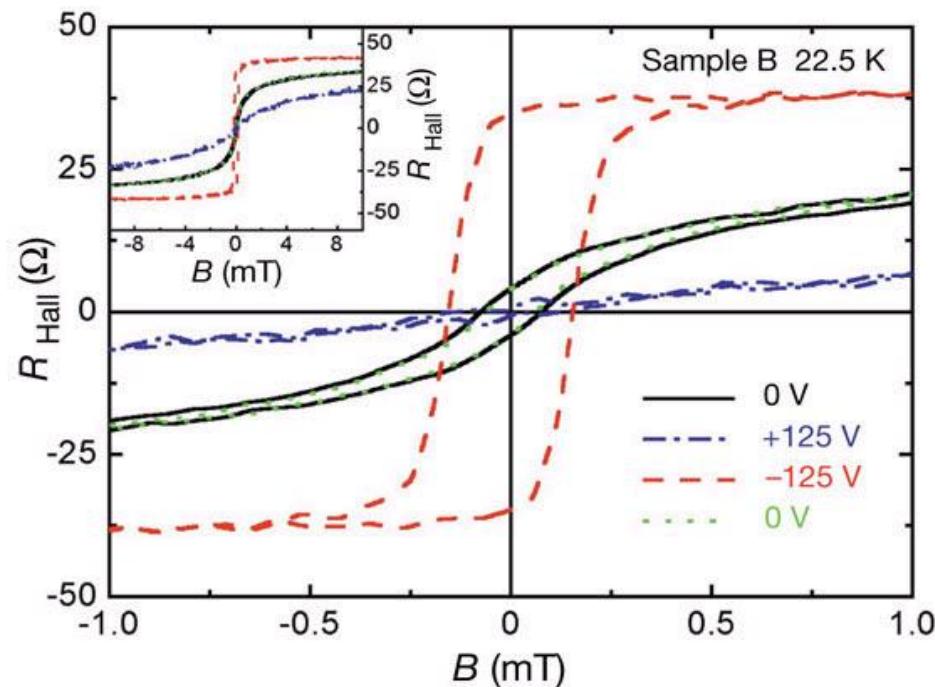
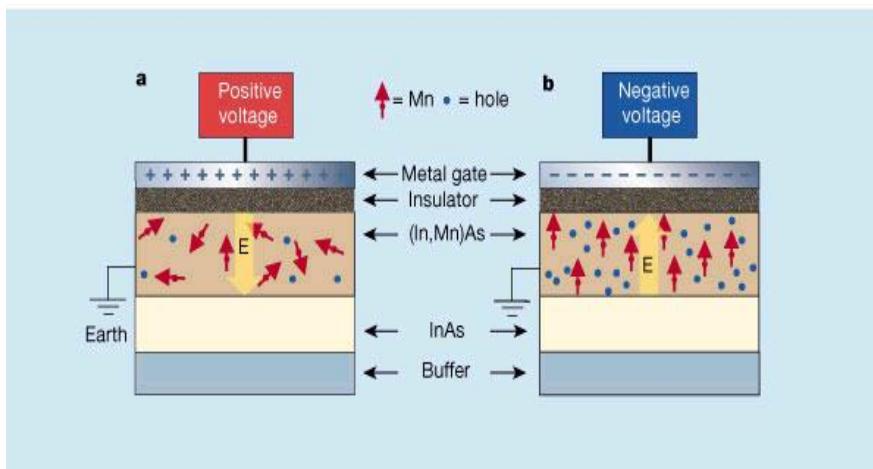




Ferromagnet/Ferroelectric material combination

Diluted magnetic semiconductor-- (In,Mn)As

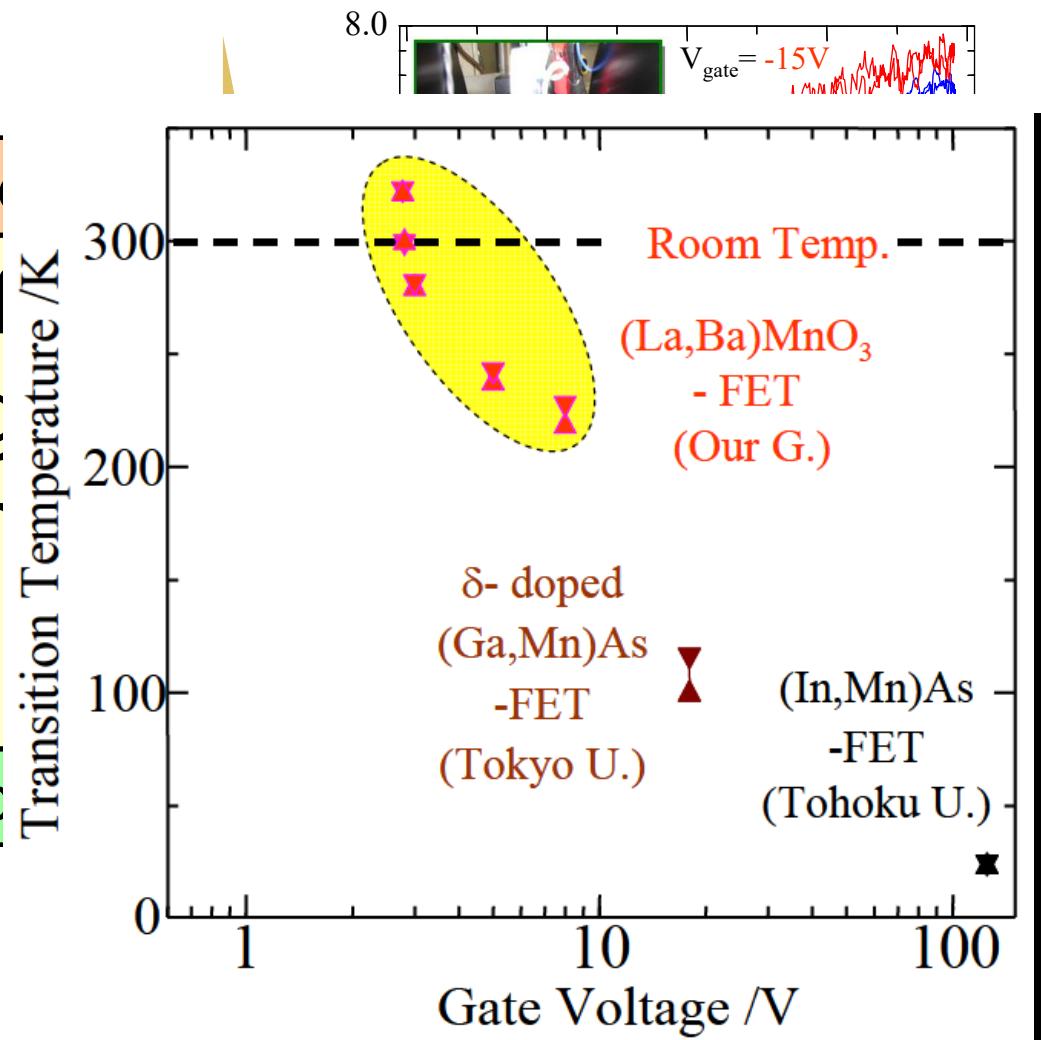
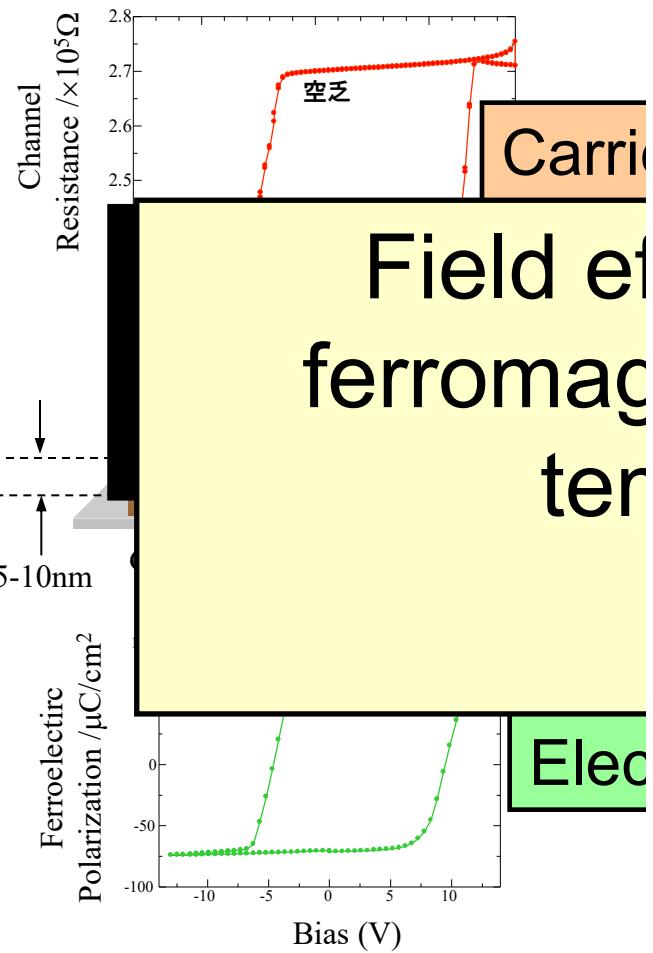
Field effect transistor



Nature 408, 944(2000)

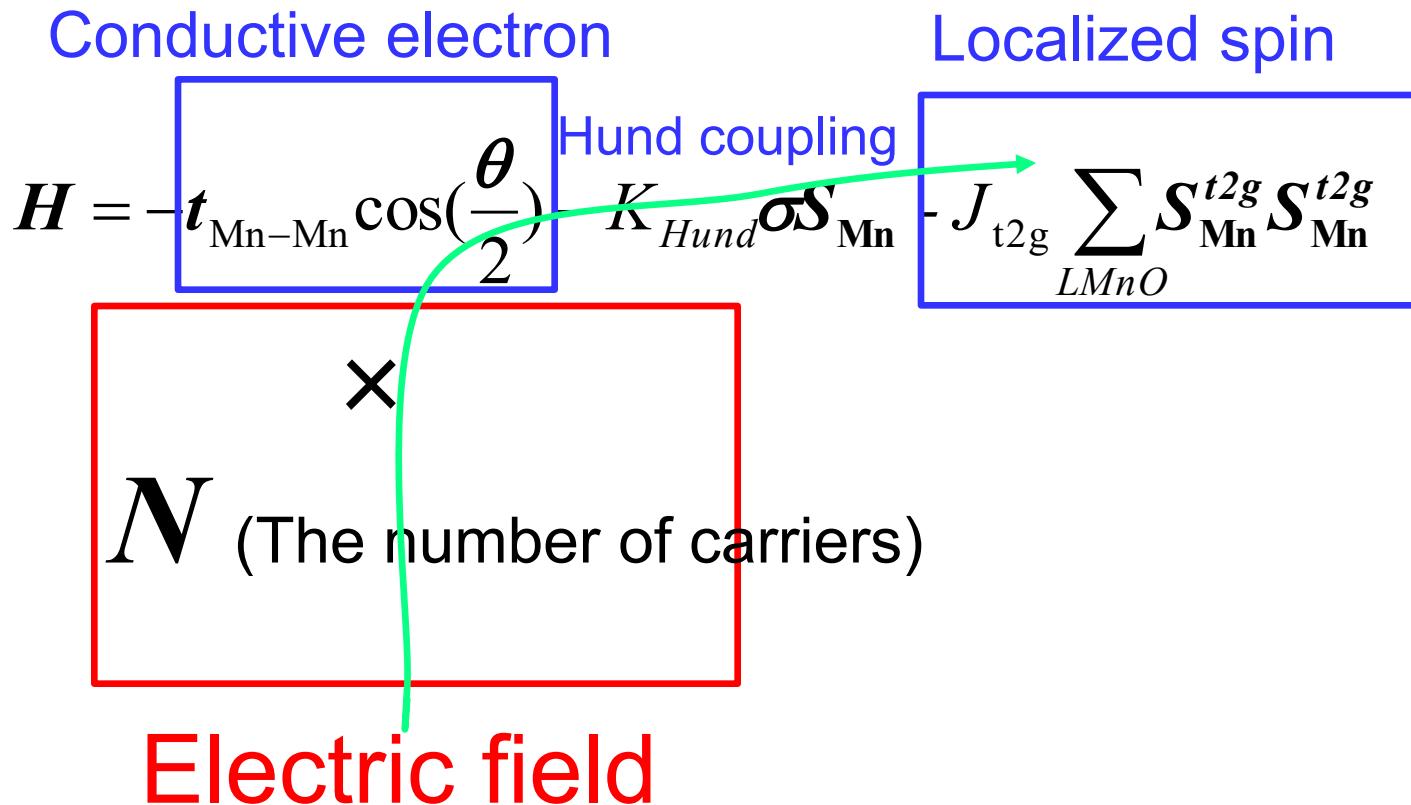


Ferromagnet/Ferroelectric material combination





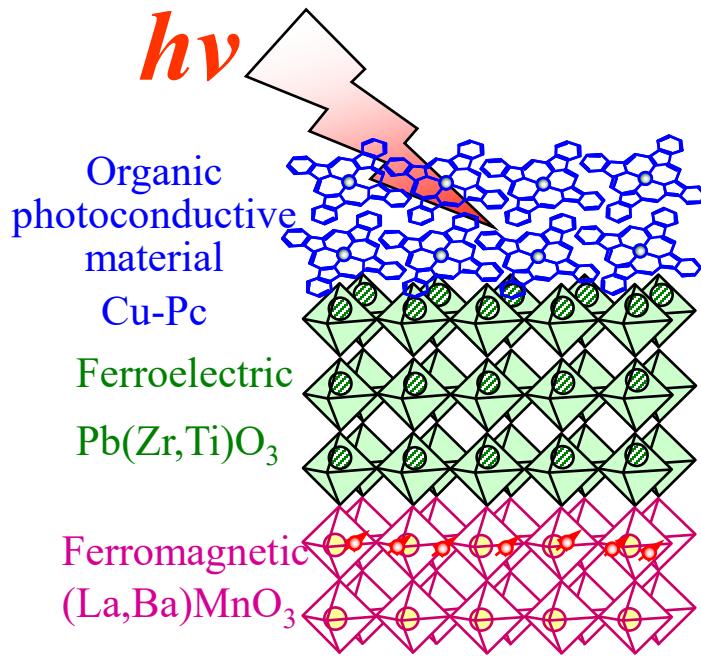
Ferromagnet/Ferroelectric material combination





Photonic/Ferroelectric/magnetic material combination

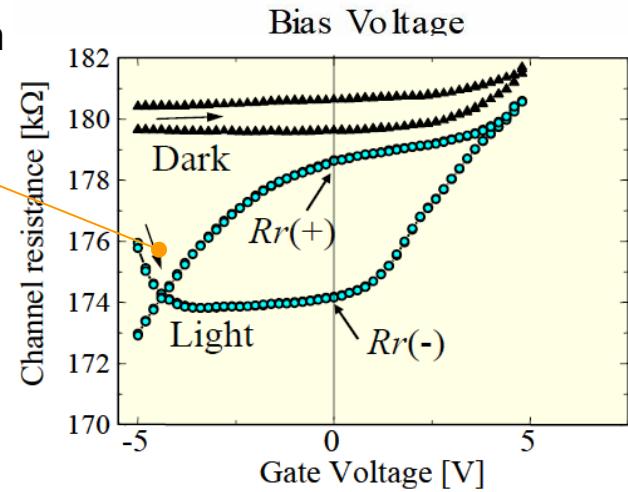
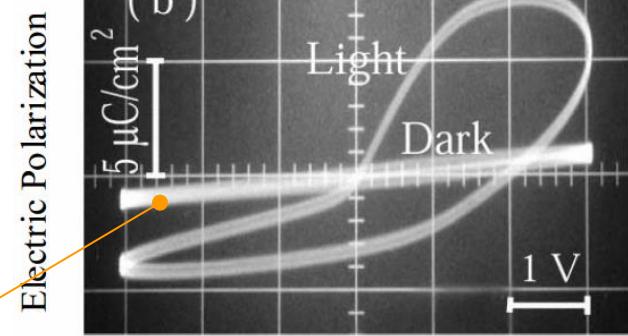
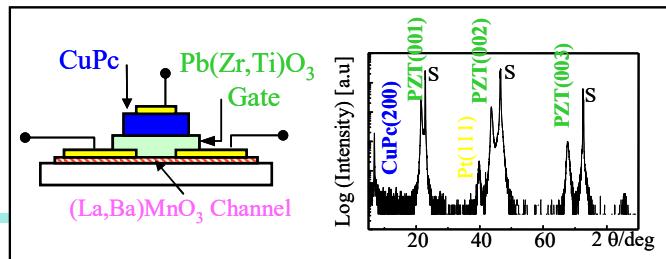
Photon → Electric dipole → Carrier spin



Decrease resistance
(by photon)

Dielectric polarization
(electric dipole)

Field effect
(Carrier / Spin)





Summary: Oxide spintronics

- (1) Introduce strain effect ----- Room temperature CMR
- (2) Introduce magnetic interaction --- Magnetic superlattice
between different layers Design of magnetic susceptibility
- (3) Integrate different functional materials ----- Ferromagnetism
+ Ferroelectric